# ADC10D020 Dual 10-Bit, 20 MSPS, 150 mW A/D Converter

**Check for Samples: ADC10D020**

## FEATURES

- **Internal Sample-and-Hold**
- **Internal Reference Capability**
- **Dual Gain Settings**
- **Offset Correction**
- **Selectable Offset Binary or 2's Complement Output**
- **Multiplexed or Parallel Output Bus**
- **Single +2.7V to 3.6V Operation**
- **Power Down and Standby Modes**

## APPLICATIONS

- **Digital Video**
- **CCD Imaging**
- **Portable Instrumentation**
- **Communications**
- **Medical Imaging**
- **Ultrasound**

## KEY SPECIFICATIONS

- **Resolution 10 Bits**
- **Conversion Rate 20 MSPS**
- **ENOB 9.5 Bits (typ)**
- **DNL 0.35 LSB (typ)**
- **Conversion Latency Parallel Outputs 2.5 Clock Cycles**
- **Multiplexed Outputs, I Data Bus 2.5 Clock Cycles**
- **Multiplexed Outputs, Q Data Bus 3 Clock Cycles**
- **PSRR 90 dB**
- **Power Consumption—Normal Operation 150 mW (typ)**
- **Power Down Mode <1 mW (typ)**
- **Fast Recovery Standby Mode 27 mW (typ)**

## DESCRIPTION

The ADC10D020 is a dual low power, high performance CMOS analog-to-digital converter that digitizes signals to 10 bits resolution at sampling rates up to 30 MSPS while consuming a typical 150 mW from a single 3.0V supply. No missing codes is ensured over the full operating temperature range. The unique two stage architecture achieves 9.5 Effective Bits over the entire Nyquist band at 20 MHz sample rate. An output formatting choice of offset binary or 2's complement coding and a choice of two gain settings eases the interface to many systems. Also allowing great flexibility of use is a selectable 10-bit multiplexed or 20-bit parallel output mode. An offset correction feature minimizes the offset error.

To ease interfacing to most low voltage systems, the digital output power pins of the ADC10D020 can be tied to a separate supply voltage of 1.5V to 3.6V, making the outputs compatible with other low voltage systems. When not converting, power consumption can be reduced by pulling the PD (Power Down) pin high, placing the converter into a low power state where it typically consumes less than 1 mW and from which recovery is less than 1 ms. Bringing the STBY (Standby) pin high places the converter into a standby mode where power consumption is about 27 mW and from which recovery is 800 ns.

The ADC10D020's speed, resolution and single supply operation makes it well suited for a variety of applications, including high speed portable applications.

Operating over the industrial ($-40° \le T_A \le +85°C$) temperature range, the ADC10D020 is available in a 48-pin TQFP package. An evaluation board is available to ease the design effort.

## Connection Diagram

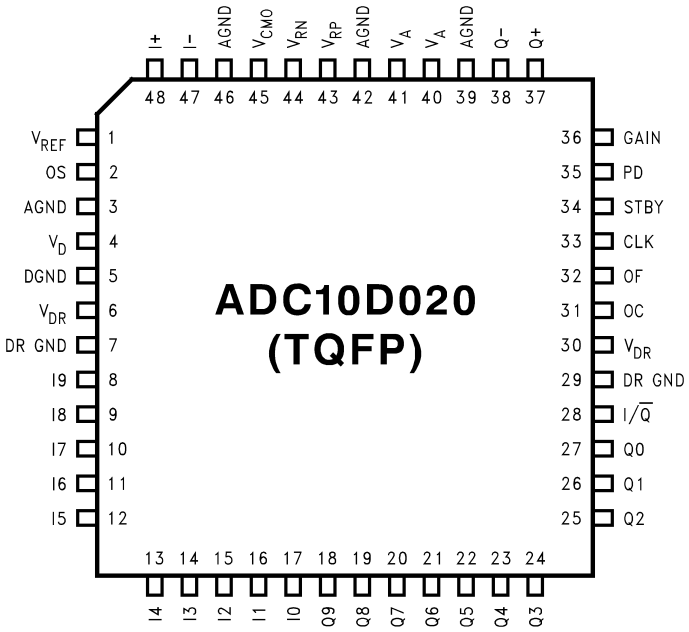
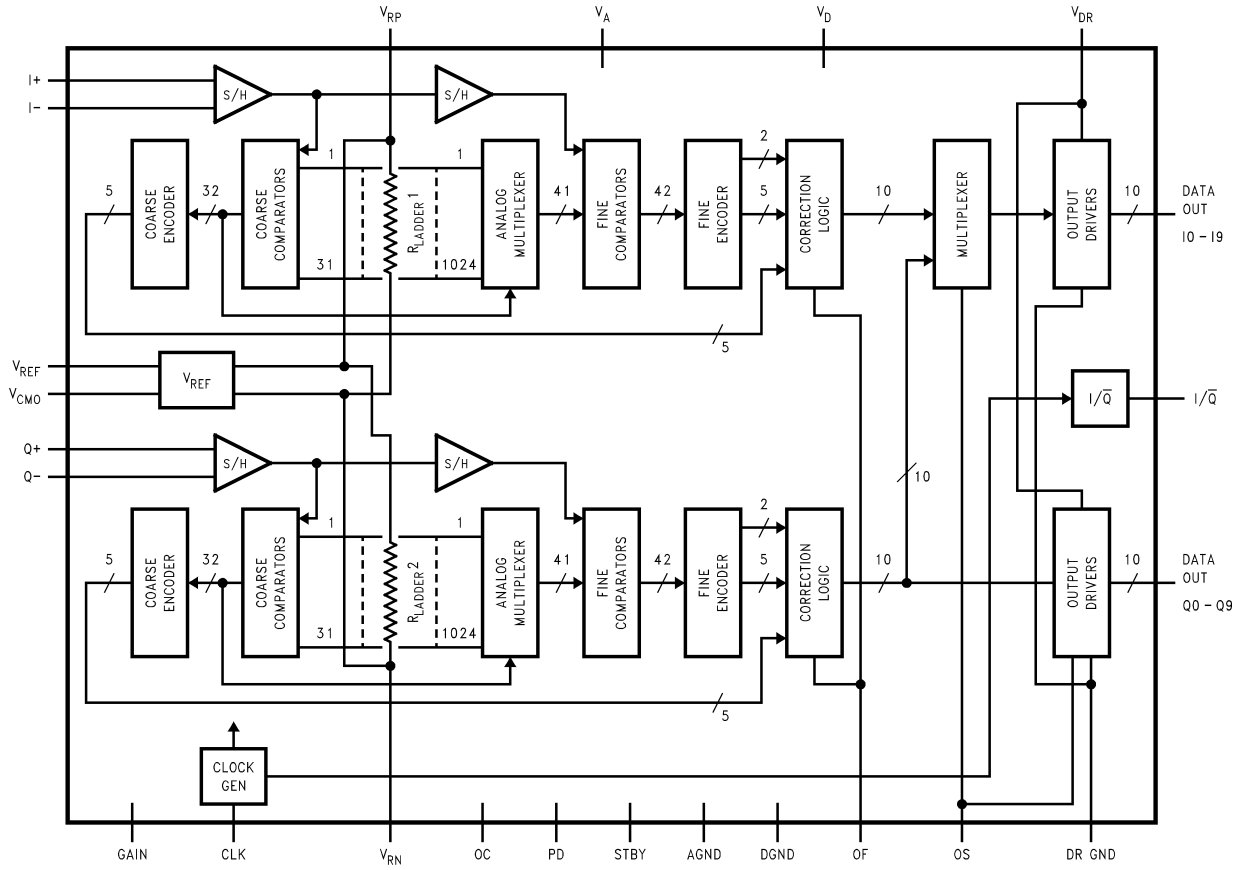
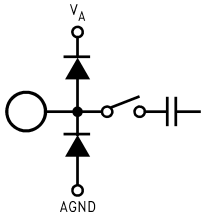
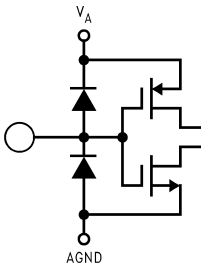
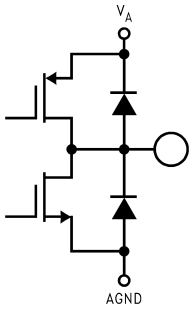
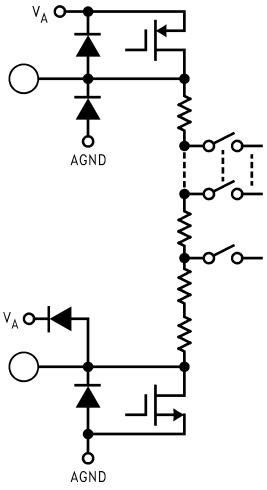



**Figure 1. TOP VIEW**
**24-Lead TQFP**
**See PFB Package**

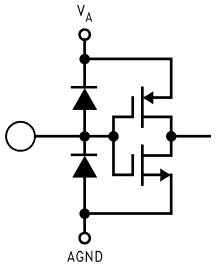
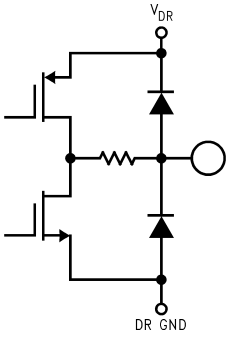
## Block Diagram



## PIN DESCRIPTIONS AND EQUIVALENT CIRCUITS

| Pin No. | Symbol | Equivalent Circuit | Description |
|---|---|---|---|
| 48<br>47 | I+<br>I− |  | Analog inputs to “I” ADC. Nominal conversion range is 1.25V to 1.75V with GAIN pin low, or 1.0V to 2.0V with GAIN pin high. |
| 37<br>38 | Q+<br>Q− | | Analog inputs to “Q” ADC. Nominal conversion range is 1.25V to 1.75V with GAIN pin low, or 1.0V to 2.0V with GAIN pin high. |
| 1 | $V_{REF}$ |  | Analog Reference Voltage input. The voltage at this pin should be in the range of 0.8V to 1.5V. With 1.0V at this pin and the GAIN pin *low*, the full scale differential inputs are 1 $V_{P-P}$. With 1.0V at this pin and the GAIN pin *high*, the full scale differential inputs are 2 $V_{P-P}$. This pin should be bypassed with a minimum 1 µF capacitor. |
| 45 | $V_{CMO}$ |  | This is an analog output which can be used as a reference source and/or to set the common mode voltage of the input. It should be bypassed with a minimum of 1 µF low ESR capacitor in parallel with a 0.1 µF capacitor. This pin has a nominal output voltage of 1.5V and has a 1 mA output source capability. |
| 43 | $V_{RP}$ |  | Top of the reference ladder. **Do not drive this pin.** Bypass this pin with a 10 µF low ESR capacitor and a 0.1 µF capacitor. |
| 44 | $V_{RN}$ | | Bottom of the reference ladder. **Do not drive this pin.** Bypass this pin with a 10 µF low ESR capacitor and a 0.1 µF capacitor. |

## PIN DESCRIPTIONS AND EQUIVALENT CIRCUITS (continued)

| Pin No. | Symbol | Equivalent Circuit | Description |
|---|---|---|---|
| 33 | CLK |   | Digital clock input for both converters. The analog inputs are sampled on the falling edge of this clock input. |
| 2 | OS | | Output Bus Select. With this pin at a logic high, both the “I” and the “Q” data are present on their respective 10-bit output buses (Parallel mode of operation). When this pin is at a logic low, the “I” and “Q” data are multiplexed onto the “I” output bus and the “Q” output lines all remain at a logic low (multiplexed mode). |
| 31 | OC | | Offset Correct pin. A low-to-high transition on this pin initiates an independent offset correction sequence for each converter, which takes 34 clock cycles to complete. During this time 32 conversions are taken and averaged. The result is subtracted from subsequent conversions. Each input pair should have 0V differential value during this entire 34 clock period. |
| 32 | OF | | Output Format pin. When this pin is LOW the output format is Offset Binary. When this pin is HIGH the output format is 2's complement. This pin may be changed asynchronously, but this will result in errors for one or two conversions. |
| 34 | STBY | | Standby pin. The device operates normally with a logic low on this and the PD (Power Down) pin. With this pin at a logic high and the PD pin at a logic low, the device is in the standby mode where it consumes just 27 mW of power. It takes just 800 ns to come out of this mode after the STBY pin is brought low. |
| 35 | PD | | Power Down pin that, when high, puts the converter into the Power Down mode where it consumes less than 1 mW of power. It takes less than 1 ms to recover from this mode after the PD pin is brought low. If both the STBY and PD pins are high simultaneously, the PD pin dominates. |
| 36 | GAIN | | This pin sets the internal signal gain at the inputs to the ADCs. With this pin low the full scale differential input peak-to-peak signal is equal to $V_{REF}$. With this pin high the full scale differential input peak-to-peak signal is equal to 2 x $V_{REF}$.. |
| 8 thru 27 | I0–I9 and Q0–Q9 |   | 3V TTL/CMOS-compatible Digital Output pins that provide the conversion results of the I and Q inputs. I0 and Q0 are the LSBs, I9 and Q9 are the MSBs. Valid data is present just after the rising edge of the CLK input in the Parallel mode. In the multiplexed mode, I-channel data is valid on I0 through I9 when the I/$\overline{Q}$ output is high and the Q-channel data is valid on I0 through I9 when the I/$\overline{Q}$ output is low. |
| 28 | I/$\overline{Q}$ | | Output data valid signal. In the multiplexed mode, this pin transitions from low to high when the data bus transitions from Q-data to I-data, and from high to low when the data bus transitions from I-data to Q-data. In the Parallel mode, this pin transitions from low to high as the output data changes. |
| 40, 41 | $V_A$ | | Positive analog supply pin. This pin should be connected to a quiet voltage source of +2.7V to +3.6V. $V_A$ and $V_D$ should have a common supply and be separately bypassed with 10 µF to 50 µF capacitors in parallel with 0.1 µF capacitors. |
| 4 | $V_D$ | | Digital supply pin. This pin should be connected to a quiet voltage source of +2.7V to +3.6V. $V_A$ and $V_D$ should have a common supply and be separately bypassed with 10 µF to 50 µF capacitors in parallel with 0.1 µF capacitors. |
| 6, 30 | $V_{DR}$ | | Digital output driver supply pins. These pins should be connected to a voltage source of +1.5V to $V_D$ and be bypassed with 10 µF to 50 µF capacitors in parallel with 0.1 µF capacitors. |
| 3, 39, 42, 46 | AGND | | The ground return for the analog supply. AGND and DGND should be connected together close to the ADC10D020 package. |
| 5 | DGND | | The ground return for the digital supply. AGND and DGND should be connected together close to the ADC10D020 package. |
| 7, 29 | DR GND | | The ground return of the digital output drivers. |

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## Absolute Maximum Ratings (1)(2)(3)

| | | |
|---|---|---|
| Positive Supply Voltages | | 3.8V |
| Voltage on Any Pin | | −0.3V to ($V_A$ or $V_D$ +0.3V) |
| Input Current at Any Pin (4) | | ±25 mA |
| Package Input Current (4) | | ±50 mA |
| Package Dissipation at $T_A$ = 25°C | | See (5) |
| ESD Susceptibility (6) | Human Body Model | 2500V |
| | Machine Model | 250V |
| Soldering Temperature, Infrared,10 sec. (7) | | 235°C |
| Storage Temperature | | −65°C to +150°C |

(1) All voltages are measured with respect to GND = AGND = DGND = 0V, unless otherwise specified.
(2) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
(3) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
(4) When the input voltage at any pin exceeds the power supplies ($V_{IN}$ < GND or $V_{IN}$ > $V_A$ or $V_D$), the current at that pin should be limited to 25 mA. The 50 mA maximum package input current rating limits the number of pins that can safely exceed the power supplies with an input current of 25 mA to two.
(5) The absolute maximum junction temperature ($T_J$max) for this device is 150°C. The maximum allowable power dissipation is dictated by $T_J$max, the junction-to-ambient thermal resistance ($\theta_{JA}$), and the ambient temperature ($T_A$), and can be calculated using the formula $P_D MAX = (T_J max - T_A)/\theta_{JA}$. In the 48-pin TQFP, $\theta_{JA}$ is 76°C/W, so $P_D$MAX = 1,645 mW at 25°C and 855 mW at the maximum operating ambient temperature of 85°C. Note that the power dissipation of this device under normal operation will typically be about 170 mW (150 mW quiescent power + 20 mW due to 1 LVTTL load on each digital output). The values for maximum power dissipation listed above will be reached only when the ADC10D020 is operated in a severe fault condition (e.g. when input or output pins are driven beyond the power supply voltages, or the power supply polarity is reversed). Obviously, such conditions should always be avoided.
(6) Human body model is 100 pF capacitor discharged through a 1.5 kΩ resistor. Machine model is 220 pF discharged through 0Ω.
(7) See AN450, “Surface Mounting Methods and Their Effect on Product Reliability”, or the section entitled “Surface Mount” found in any post 1986 Texas Instruments Linear Data Book, for other methods of soldering surface mount devices.

## Operating Ratings (1)(2)

| | | |
|---|---|---|
| Operating Temperature Range | | −40°C ≤ $T_A$ ≤ +85°C |
| $V_A$, $V_D$ Supply Voltage | | +2.7V to +3.6V |
| $V_{DR}$ Supply Voltage | | +1.5V to $V_D$ |
| $V_{IN}$ Differential Voltage Range | GAIN = Low | ±$V_{REF}$/2 |
| | GAIN = High | ±$V_{REF}$ |
| $V_{CM}$ Input Common Mode Range | GAIN = Low | $V_{REF}$/4 to ($V_A$–$V_{REF}$/4) |
| | GAIN = High | $V_{REF}$/2 to ($V_A$–$V_{REF}$/2) |
| $V_{REF}$ Voltage Range | | 0.8V to 1.5V |
| Digital Input Pins Voltage Range | | −0.3V to ($V_A$ +0.3V) |

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
(2) All voltages are measured with respect to GND = AGND = DGND = 0V, unless otherwise specified.

## Converter Electrical Characteristics

The following specifications apply for $V_A = V_D = V_{DR}$ = +3.0 $V_{DC}$, $V_{REF}$ = 1.0 $V_{DC}$, GAIN = OF = 0V, OS = 3.0V, $V_{IN}$ (a.c. coupled) = FSR = 1.0 $V_{P-P}$, $C_L$ = 15 pF, $f_{CLK}$ = 20 MHz, 50% Duty Cycle, $R_S$ = 50Ω, $t_{rc} = t_{fc}$ < 4 ns, NOT offset corrected. **Boldface limits apply for $T_A = T_{MIN}$ to $T_{MAX}$:** all other limits $T_A$ = 25°C (1).

| Symbol | Parameter | Conditions | Typical (2) | Limits (3) | Units (Limits) |
|---|---|---|---|---|---|
| **STATIC CONVERTER CHARACTERISTICS** | | | | | |
| INL | Integral Non-Linearity | | ±0.65 | **±1.8** | LSB (max) |
| DNL | Differential Non-Linearity | | ±0.35 | **+1.2**<br>**−1.0** | LSB (max)<br>LSB (min) |
| | Resolution with No Missing Codes | | | **10** | Bits |
| $V_{OFF}$ | Offset Error | Without Offset Correction | −5 | **+10**<br>**−16** | LSB (max)<br>LSB (min) |
| | | With Offset Correction | +0.5 | **+2.0**<br>**−1.5** | LSB (max)<br>LSB (min) |
| GE | Gain Error | | −4 | **+6**<br>**−14** | %FS (max)<br>%FS (min) |
| **DYNAMIC CONVERTER CHARACTERISTICS** | | | | | |
| ENOB | Effective Number of Bits | $f_{IN}$ = 1.0 MHz, $V_{IN}$ = FSR −0.1 dB | 9.5 | | Bits |
| | | $f_{IN}$ = 4.7 MHz, $V_{IN}$ = FSR −0.1 dB | 9.5 | **9.0** | Bits (min) |
| | | $f_{IN}$ = 9.5 MHz, $V_{IN}$ = FSR −0.1 dB | 9.5 | | Bits |
| | | $f_{IN}$ = 19.5 MHz, $V_{IN}$ = FSR −0.1 dB | 9.5 | | Bits |
| SINAD | Signal-to-Noise Plus Distortion Ratio | $f_{IN}$ = 1.0 MHz, $V_{IN}$ == FSR −0.1 dB | 59 | | dB |
| | | $f_{IN}$ = 4.7 MHz, $V_{IN}$ = FSR −0.1 dB | 59 | **56** | dB (min) |
| | | $f_{IN}$ = 9.5 MHz, $V_{IN}$ = FSR −0.1 dB | 59 | | dB |
| | | $f_{IN}$ = 19.5 MHz, $V_{IN}$ = FSR −0.1 dB | 59 | | dB |
| SNR | Signal-to-Noise Ratio | $f_{IN}$ = 1.0 MHz, $V_{IN}$ = FSR −0.1 dB | 59 | | dB |
| | | $f_{IN}$ = 4.7 MHz, $V_{IN}$ = FSR −0.1 dB | 59 | **56** | dB (min) |
| | | $f_{IN}$ = 9.5 MHz, $V_{IN}$ = FSR −0.1 dB | 59 | | dB |
| | | $f_{IN}$ = 19.5 MHz, $V_{IN}$ = FSR −0.1 dB | 59 | | dB |
| THD | Total Harmonic Distortion | $f_{IN}$ = 1.0 MHz, $V_{IN}$ = FSR −0.1 dB | −73 | | dB |
| | | $f_{IN}$ = 4.7 MHz, $V_{IN}$ = FSR −0.1 dB | −73 | **−62** | dB (min) |
| | | $f_{IN}$ = 9.5 MHz, $V_{IN}$ = FSR −0.1 dB | −73 | | dB |
| | | $f_{IN}$ = 19.5 MHz, $V_{IN}$ = FSR −0.1 dB | −73 | | dB |
| HS2 | Second Harmonic | $f_{IN}$ = 1.0 MHz, $V_{IN}$ = FSR −0.1 dB | −84 | | dB |
| | | $f_{IN}$ = 4.7 MHz, $V_{IN}$ = FSR −0.1 dB | −92 | | dB |
| | | $f_{IN}$ = 9.5 MHz, $V_{IN}$ = FSR −0.1 dB | −87 | | dB |
| | | $f_{IN}$ = 19.5 MHz, $V_{IN}$ = FSR −0.1 dB | −87 | | dB |
| HS3 | Third Harmonic | $f_{IN}$ = 1.0 MHz, $V_{IN}$ = FSR −0.1 dB | −80 | | dB |
| | | $f_{IN}$ = 4.7 MHz, $V_{IN}$ = FSR −0.1 dB | −78 | | dB |
| | | $f_{IN}$ = 9.5 MHz, $V_{IN}$ = FSR −0.1 dB | −78 | | dB |
| | | $f_{IN}$ = 19.5 MHz, $V_{IN}$ = FSR −0.1 dB | −78 | | dB |
| SFDR | Spurious Free Dynamic Range | $f_{IN}$ = 1.0 MHz, $V_{IN}$ = FSR −0.1 dB | 76 | | dB |
| | | $f_{IN}$ = 4.7 MHz, $V_{IN}$ = FSR −0.1 dB | 75 | | dB |
| | | $f_{IN}$ = 9.5 MHz, $V_{IN}$ = FSR −0.1 dB | 75 | | dB |
| | | $f_{IN}$ = 19.5 MHz, $V_{IN}$ = FSR −0.1 dB | 74 | | dB |

(1) The inputs are protected as shown below. Input voltage magnitude up to 300 mV beyond the supply rails will not damage this device. However, errors in the A/D conversion can occur if the input goes beyond the limits given in these tables. See Figure 2

(2) Typical figures are at $T_J$ = 25°C, and represent most likely parametric norms.

(3) Test limits are specified to TI's AOQL (Average Outgoing Quality Level). Performance is ensured only at $V_{REF}$ = 1.0V and a clock duty cycle of 50%. The limits for $V_{REF}$ and clock duty cycle specify the range over which reasonable performance is expected. Tests are performed and limits specified with clock low and high levels of 0.3V and $V_D$ − 0.3V, respectively.

## Converter Electrical Characteristics (continued)

The following specifications apply for $V_A = V_D = V_{DR} = +3.0\ V_{DC}$, $V_{REF} = 1.0\ V_{DC}$, GAIN = OF = 0V, OS = 3.0V, $V_{IN}$ (a.c. coupled) = FSR = 1.0 $V_{P-P}$, $C_L$ = 15 pF, $f_{CLK}$ = 20 MHz, 50% Duty Cycle, $R_S = 50\Omega$, $t_{rc} = t_{fc} < 4$ ns, NOT offset corrected. **Boldface limits apply for $T_A = T_{MIN}$ to $T_{MAX}$:** all other limits $T_A = 25°C$ (1).

| Symbol | Parameter | Conditions | | Typical (2) | Limits (3) | Units (Limits) |
|---|---|---|---|---|---|---|
| IMD | Intermodulation Distortion | $f_{IN1} < 4.9$ MHz, $V_{IN}$ = FSR −6.1 dB<br>$f_{IN2} < 5.1$ MHz, $V_{IN}$ = FSR −6.1 dB | | 65 | | dB |
| | Overrange Output Code | $(V_{IN+} - V_{IN-}) > 1.1V$ | | | **1023** | |
| | Underrange Output Code | $(V_{IN+} - V_{IN-}) < -1.1V$ | | | **0** | |
| FPBW | Full Power Bandwidth | | | 140 | | MHz |
| **INTER-CHANNEL CHARACTERISTICS** | | | | | | |
| | Crosstalk | 1 MHz input to tested channel, 4.75 MHz input to other channel | | −90 | | dB |
| | Channel - Channel Aperture Delay Match | $f_{IN}$ = 8 MHz | | 8.5 | | ps |
| | Channel - Channel Gain Matching | | | 0.03 | | %FS |
| **REFERENCE AND ANALOG CHARACTERISTICS** | | | | | | |
| $V_{IN}$ | Analog Differential Input Range | Gain Pin = AGND | | 1 | | $V_{P-P}$ |
| | | Gain Pin = $V_A$ | | 2 | | $V_{P-P}$ |
| $C_{IN}$ | Analog Input Capacitance (each input) | Clock High | | 6 | | pF |
| | | Clock Low | | 3 | | pF |
| $R_{IN}$ | Analog Differential Input Resistance | | | 27 | | kΩ |
| $V_{REF}$ | Reference Voltage | | | 1.0 | 0.8 | V (min) |
| | | | | | 1.5 | V (max) |
| $I_{REF}$ | Reference Input Current | | | <1 | | µA |
| $V_{CMO}$ | Common Mode Voltage Output | 1 mA load to ground (sourcing current) | | 1.5 | **1.35** | V (min) |
| | | | | | **1.6** | V (max) |
| TC $V_{CMO}$ | Common Mode Voltage Temperature Coefficient | | | 20 | | ppm/°C |
| **DIGITAL INPUT CHARACTERISTICS** | | | | | | |
| $V_{IH}$ | Logical “1” Input Voltage | $V_D$ = +2.7V | | | **2.0** | V (min) |
| $V_{IL}$ | Logical “0” Input Voltage | $V_D$ = +3.6V | | | **0.5** | V (max) |
| $I_{IH}$ | Logical “1” Input Current | $V_{IH} = V_D$ | | <1 | | µA |
| $I_{IL}$ | Logical “0” Input Current | $V_{IL}$ = DGND | | >−1 | | µA |
| **DIGITAL OUTPUT CHARACTERISTICS** | | | | | | |
| $V_{OH}$ | Logical “1” Output Voltage | $V_{DR}$ = +2.7V, $I_{OUT}$ = −0.5 mA | | | **$V_{DR}$ −0.3V** | V (min) |
| $V_{OL}$ | Logical “0” Output Voltage | $V_{DR}$ = +2.7V, $I_{OUT}$ = 1.6 mA | | | **0.4** | V (max) |
| $+I_{SC}$ | Output Short Circuit Source Current | $V_{OUT}$ = 0V | Parallel Mode | −7 | | mA |
| | | | Multiplexed Mode | −14 | | mA |
| $-I_{SC}$ | Output Short Circuit Sink Current | $V_{OUT} = V_{DR}$ | Parallel Mode | 7 | | mA |
| | | | Multiplexed Mode | 14 | | mA |
| **POWER SUPPLY CHARACTERISTICS** | | | | | | |
| $I_A + I_D$ | Core Supply Current | PD = LOW, STBY = LOW, dc input | | 47.6 | **55** | mA (max) |
| | | PD = LOW, STBY = HIGH | | 8.8 | | mA |
| | | PD = HIGH, STBY = LOW or HIGH | | 0.22 | | mA |

## Converter Electrical Characteristics (continued)

The following specifications apply for $V_A = V_D = V_{DR}$ = +3.0 $V_{DC}$, $V_{REF}$ = 1.0 $V_{DC}$, GAIN = OF = 0V, OS = 3.0V, $V_{IN}$ (a.c. coupled) = FSR = 1.0 $V_{P-P}$, $C_L$ = 15 pF, $f_{CLK}$ = 20 MHz, 50% Duty Cycle, $R_S$ = 50Ω, $t_{rc} = t_{fc}$ < 4 ns, NOT offset corrected. **Boldface limits apply for $T_A = T_{MIN}$ to $T_{MAX}$:** all other limits $T_A$ = 25°C (1).

| Symbol | Parameter | Conditions | Typical (2) | Limits (3) | Units (Limits) |
|---|---|---|---|---|---|
| $I_{DR}$ | Digital Output Driver Supply Current (4) | PD = LOW, STBY = LOW, dc input | 1.3 | **1.4** | mA (max) |
| | | PD = LOW, STBY = HIGH | 0.1 | | mA |
| | | PD = HIGH, STBY = LOW or HIGH | 0.1 | | mA |
| PWR | Power Consumption | PD = LOW, STBY = LOW, dc input | 150 | 169 | mW (max) |
| | | PD = LOW, STBY = LOW, 1 MHz Input | 178 | | mW |
| | | PD = LOW, STBY = HIGH | 27 | | mW |
| | | PD = HIGH, STBY = LOW or HIGH | <1 | | mW |
| PSRR1 | Power Supply Rejection Ratio | Change in Full Scale with 2.7V to 3.6V Supply Change | 90 | | dB |
| PSRR2 | Power Supply Rejection Ratio | Rejection at output with 20 MHz, 250 $mV_{P-P}$ Riding on $V_A$ and $V_D$ | 52 | | dB |

(4) $I_{DR}$ is the current consumed by the switching of the output drivers and is primarily determined by the load capacitance on the output pins, the supply voltage, $V_{DR}$, and the rate at which the outputs are switching (which is signal dependent). $I_{DR} = V_{DR} (C_O \times f_O + C_1 \times f_1 + ... + C_9 \times f_9)$ where $V_{DR}$ is the output driver power supply voltage, $C_n$ is the total capacitance on the output pin, and $f_n$ is the average frequency at which that pin is toggling.

## AC Electrical Characteristics OS = Low (Multiplexed Mode)

The following specifications apply for $V_A = V_D = V_{DR}$ = +3.0$V_{DC}$, $V_{REF}$ = 1.0 $V_{DC}$, GAIN = OF = 0V, OS = 0V, $V_{IN}$ (a.c. coupled) = FSR = 1.0 $V_{P-P}$, $C_L$ = 15 pF, $f_{CLK}$ = 20 MHz, 50% Duty Cycle, $R_S$ = 50Ω, $t_{rc} = t_{fc}$ < 4 ns, NOT offset corrected. **Boldface limits apply for $T_A = T_{MIN}$ to $T_{MAX}$:** all other limits $T_A$ = 25°C (1)

| Symbol | Parameter | Conditions | Typical (2) | Limits (3) | Units (Limits) |
|---|---|---|---|---|---|
| $f_{CLK^1}$ | Maximum Clock Frequency | | 30 | **20** | MHz (min) |
| $f_{CLK^2}$ | Minimum Clock Frequency | | 1 | | MHz |
| | Duty Cycle | | 50 | **30**<br>**70** | % (min)<br>% (max) |
| | Pipeline Delay (Latency) | | | | |
| | I Data | | | **2.5** | Clock Cycles |
| | Q Data | | | **3.0** | Clock Cycles |
| $t_r$, $t_f$ | Output Rise and Fall Times | | 4 | | ns |
| $t_{OC}$ | Offset Correction Pulse Width | | | **10** | ns (min) |
| $t_{OD}$ | Output Delay from CLK Edge to Data Valid | | 13 | **18** | ns (max) |
| $t_{DIQ}$ | I/Q Output Delay | | 13 | | ns |
| $t_{SKEW}$ | I/Q to Data Delay | | ±200 | | ps |
| $t_{AD}$ | Sampling (Aperture) Delay | | 2.4 | | ns |
| $t_{AJ}$ | Aperture Jitter | | <10 | | ps (rms) |
| $t_{VALID}$ | Data Valid Time | | 21 | | ns |
| | Overrange Recovery Time | Differential $V_{IN}$ step from 1.5V to 0V | 50 | | ns |
| $t_{WUPD}$ | PD Low to 1/2 LSB Accurate Conversion (Wake-Up Time) | | <1 | | ms |
| $t_{WUSB}$ | STBY Low to 1/2 LSB Accurate Conversion (Wake-Up Time) | | 800 | | ns |

(1) The inputs are protected as shown below. Input voltage magnitude up to 300 mV beyond the supply rails will not damage this device. However, errors in the A/D conversion can occur if the input goes beyond the limits given in these tables. See Figure 2

(2) Typical figures are at $T_J$ = 25°C, and represent most likely parametric norms.

(3) Test limits are specified to TI's AOQL (Average Outgoing Quality Level). Performance is ensured only at $V_{REF}$ = 1.0V and a clock duty cycle of 50%. The limits for $V_{REF}$ and clock duty cycle specify the range over which reasonable performance is expected. Tests are performed and limits specified with clock low and high levels of 0.3V and $V_D$ − 0.3V, respectively.

## AC Electrical Characteristics OS = High (Parallel Mode)

The following specifications apply for $V_A$ = +3.0 $V_{DC}$, $V_D$ = +3.0 $V_{DC}$, $V_{DR}$ = +3.0$V_{DC}$, $V_{REF}$ = 1.0 $V_{DC}$, GAIN = OF = 0V, OS = 3.0V, $V_{IN}$ (a.c. coupled) = FSR = 1.0 $V_{P-P}$, $C_L$ = 15 pF, $f_{CLK}$ = 20 MHz, 50% Duty Cycle, $R_S$ = 50Ω, $t_{rc}$ = $t_{fc}$ < 4 ns, NOT offset corrected. **Boldface limits apply for $T_A$ = $T_{MIN}$ to $T_{MAX}$:** all other limits $T_A$ = 25°C (1)

| Symbol | Parameter | Conditions | Typical (2) | Limits (3) | Units (Limits) |
|---|---|---|---|---|---|
| $f_{CLK}$[1] | Maximum Clock Frequency | | 30 | **20** | MHz (min) |
| $f_{CLK}$[2] | Minimum Clock Frequency | | 1 | | MHz |
| | Duty Cycle | | 50 | **30**<br>**70** | % (min)<br>% (max) |
| | Pipeline Delay (Latency) | | | **2.5** | Conv Cycles |
| $t_r$, $t_f$ | Output Rise and Fall Times | | 7 | | ns |
| $t_{oc}$ | OC Pulse Width | | | **10** | ns |
| $t_{OD}$ | Output Delay from CLK Edge to Data Valid | | 15 | **21** | ns (max) |
| $t_{DIQ}$ | I/Q Output Delay | | 13 | | ns |
| $t_{AD}$ | Sampling (Aperture) Delay | | 2.4 | | ns |
| $t_{AJ}$ | Aperture Jitter | | <10 | | ps (rms) |
| $t_{VALID}$ | Data Valid Time | | 43 | | ns |
| | Overrange Recovery Time | Differential $V_{IN}$ step from 1.5V to 0V | 50 | | ns |
| $t_{WUPD}$ | PD Low to 1/2 LSB Accurate Conversion (Wake-Up Time) | | <1 | | ms |
| $t_{WUSB}$ | STBY Low to 1/2 LSB Accurate Conversion (Wake-Up Time) | | 800 | | ns |

(1) The inputs are protected as shown below. Input voltage magnitude up to 300 mV beyond the supply rails will not damage this device. However, errors in the A/D conversion can occur if the input goes beyond the limits given in these tables. See Figure 2

(2) Typical figures are at $T_J$ = 25°C, and represent most likely parametric norms.

(3) Test limits are specified to TI's AOQL (Average Outgoing Quality Level). Performance is ensured only at $V_{REF}$ = 1.0V and a clock duty cycle of 50%. The limits for $V_{REF}$ and clock duty cycle specify the range over which reasonable performance is expected. Tests are performed and limits specified with clock low and high levels of 0.3V and $V_D$ − 0.3V, respectively.

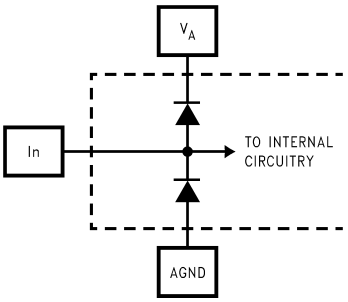



**Figure 2.**

## Timing Diagrams

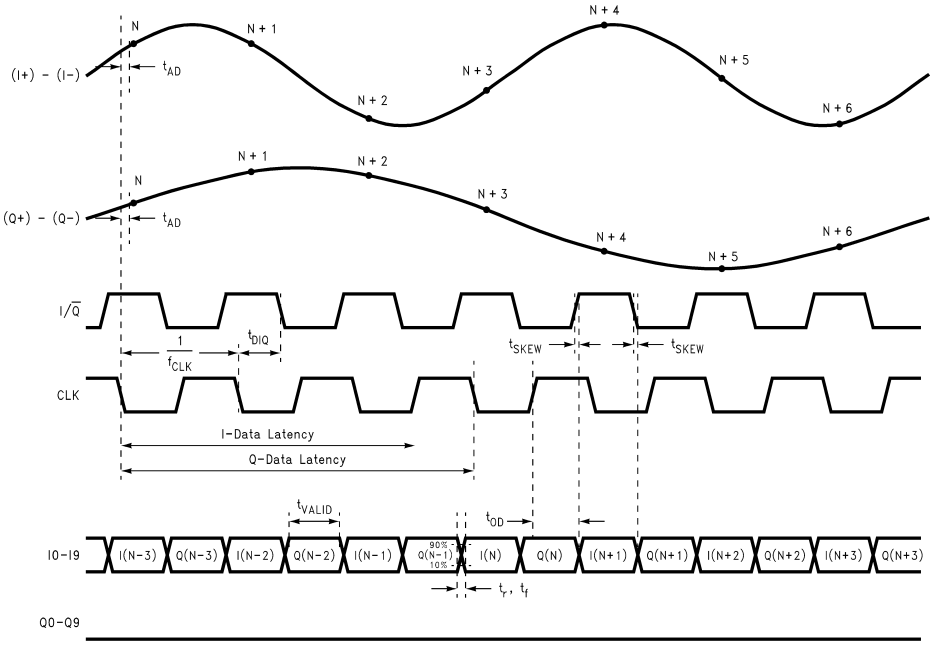



**Figure 3. ADC10D020 Timing Diagram for Multiplexed Mode**

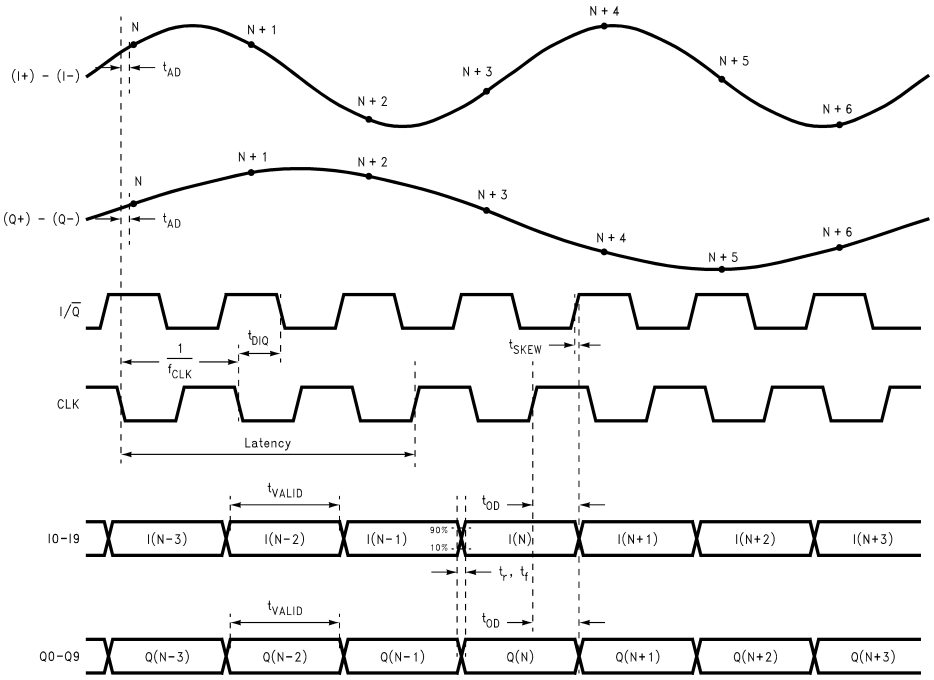



**Figure 4. ADC10D020 Timing Diagram for Parallel Mode**

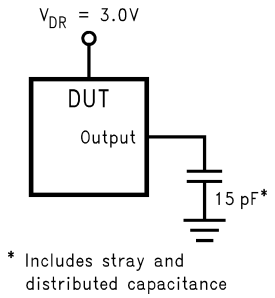



**Figure 5. AC Test Circuit**

## Specification Definitions

**APERTURE (SAMPLING) DELAY** is that time required after the fall of the clock input for the sampling switch to open. The Sample/Hold circuit effectively stops capturing the input signal and goes into the "hold" mode $t_{AD}$ after the clock goes low.

**APERTURE JITTER** is the variation in aperture delay from sample to sample. Aperture jitter shows up as input noise.

**CLOCK DUTY CYCLE** is the ratio of the time that the clock waveform is high to the total time of one clock period.

**CROSSTALK** is coupling of energy from one channel into the other channel.

**DIFFERENTIAL NON-LINEARITY (DNL)** is the measure of the maximum deviation from the ideal step size of 1 LSB. Measured at 20 MSPS with a ramp input.

**EFFECTIVE NUMBER OF BITS (ENOB, or EFFECTIVE BITS)** is another method of specifying Signal-to-Noise and Distortion Ratio, or SINAD. ENOB is defined as (SINAD − 1.76)/6.02 and says that the converter is equivalent to a perfect ADC of this (ENOB) number of bits.

**FULL POWER BANDWIDTH (FPBW)** is the frequency at which the magnitude of the reconstructed output fundamental drops 3 dB below its 1 MHz value.

**GAIN ERROR** is the difference between the ideal and actual differences between the input levels at which the first and last code transitions occur. That is, how far this difference is from Full Scale.

**INTEGRAL NON LINEARITY (INL)** is a measure of the maximum deviation of each individual code from a line drawn from zero scale (½ LSB below the first code transition) through positive full scale (½ LSB above the last code transition). The deviation of any given code from this straight line is measured from the center of that code value. The end point test method is used. Measured at 20 MSPS with a ramp input.

**INTERMODULATION DISTORTION (IMD)** is the creation of spectral components that are not present in the input as a result of two sinusoidal frequencies being applied to the ADC input at the same time. It is defined as the ratio of the power in the second and third order intermodulation products to the total power in one of the original frequencies. IMD is usually expressed in dB.

**LSB (LEAST SIGNIFICANT BIT)** is the bit that has the smallest value of weight of all bits. This value is

$$m * V_{REF}/2^n \quad (1)$$

where

- "m" is the reference scale factor
- "n" is the ADC resolution, which is 10 in the case of the ADC10D020
- The value of "m" is determined by the logic level at the gain pin and has a value of 1 when the gain pin is at a logic low and a value of 2 when the gain pin is at a logic high.

**MISSING CODES** are those output codes that are skipped or will never appear at the ADC outputs. These codes cannot be reached with any input value.

**MSB (MOST SIGNIFICANT BIT)** is the bit that has the largest value or weight. Its value is one half of full scale.

**OFFSET ERROR** is a measure of how far the mid-scale transition point is from the ideal zero voltage input.

**OUTPUT DELAY** is the time delay after the rising edge of the input clock before the data update is present at the output pins.

**OVERRANGE RECOVERY TIME** is the time required after the differential input voltages goes from 1.5V to 0V for the converter to recover and make a conversion with its rated accuracy.

**PIPELINE DELAY (LATENCY)** is the number of clock cycles between initiation of conversion and when that data is presented to the output driver stage. New data is available at every clock cycle, but the data output lags the input by the Pipeline Delay plus the Output Delay.

**POWER SUPPLY REJECTION RATIO (PSRR)** can be one of two specifications. PSRR1 (DC PSRR) is the ratio of the change in full scale gain error that results from a power supply voltage change from 2.7V to 3.6V. PSRR2 (AC PSRR) is measured with a 20 MHz, 250 $mV_{P-P}$ signal riding upon the power supply and is the ratio of the signal amplitude on the power supply pins to the amplitude of that frequency at the output. PSRR is expressed in dB.

**SIGNAL TO NOISE RATIO (SNR)** is the ratio, expressed in dB, of the rms value of the fundamental signal at the output to the rms value of the sum of all other spectral components below one-half the sampling frequency, not including harmonics or dc.

**SIGNAL TO NOISE PLUS DISTORTION (S/(N+D) or SINAD)** is the ratio, expressed in dB, of the rms value of the fundamental signal at the output to the rms value of all of the other spectral components below half the clock frequency, including harmonics but excluding dc.

**SPURIOUS FREE DYNAMIC RANGE (SFDR)** is the difference, expressed in dB, between the rms values of the fundamental signal at the output and the peak spurious signal, where a spurious signal is any signal present in the output spectrum that is not present at the input.

**TOTAL HARMONIC DISTORTION (THD)** is the ratio, expressed in dB, of the rms total of the first 9 harmonic levels to the level of the input frequency. THD is calculated as

$$THD = 20 \log \sqrt{\frac{f_2^2 + f_3^2 + f_4^2 + f_5^2 + f_6^2 + f_7^2 + f_8^2 + f_9^2 + f_{10}^2}{f_1^2}} \quad (2)$$

where

- $f_1$ is the RMS power of the fundamental (output) frequency
- $f_2$ through $f_{10}$ are the RMS power of the first 9 harmonic frequencies in the output spectrum

## Typical Performance Characteristics

$V_A = V_D = V_{DR} = 3.0V$, $f_{CLK} = 20$ MHz, unless otherwise specified

**Typical INL**

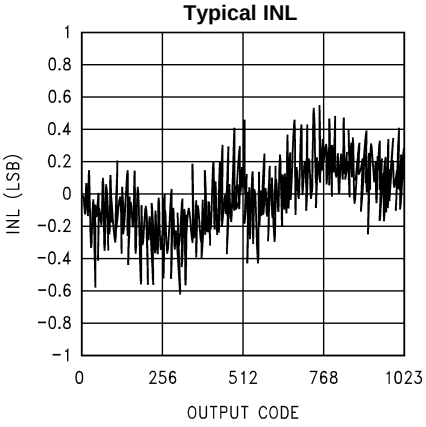



**Figure 6.**

**INL vs. Supply Voltage**

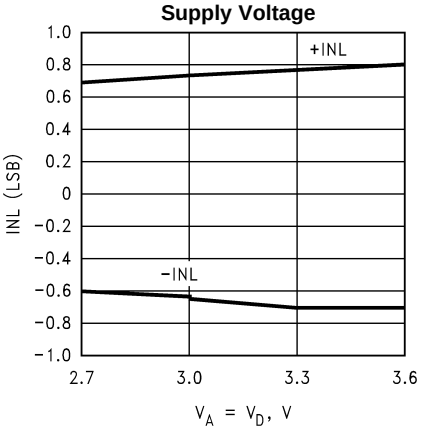



**Figure 7.**

**INL vs. $V_{REF}$**

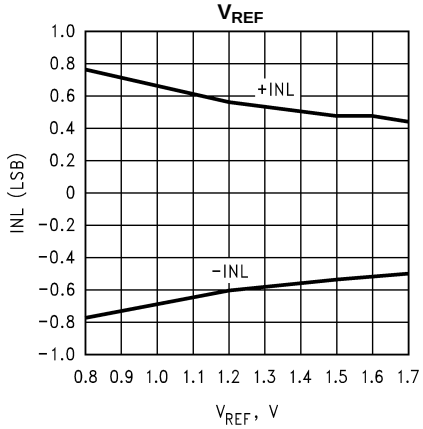



**Figure 8.**

**INL vs. $f_{CLK}$**

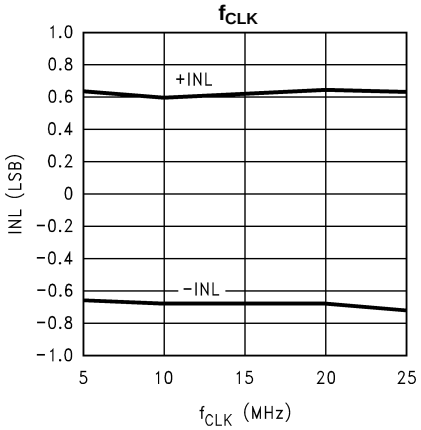



**Figure 9.**

**INL vs. Clock Duty Cycle**

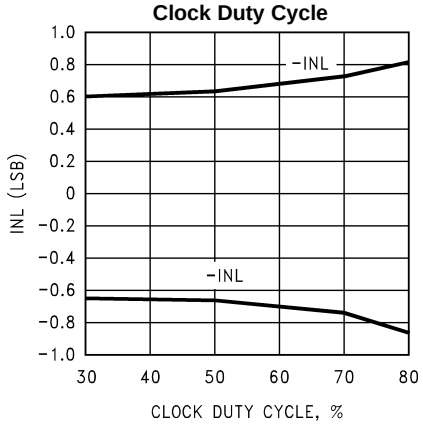



**Figure 10.**

**INL vs. Temperature**

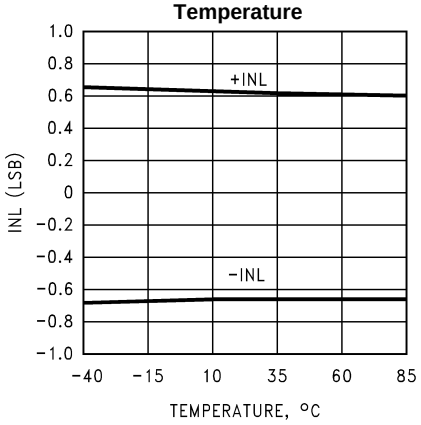



**Figure 11.**

## Typical Performance Characteristics (continued)

$V_A = V_D = V_{DR} = 3.0V$, $f_{CLK} = 20$ MHz, unless otherwise specified

**Typical DNL**

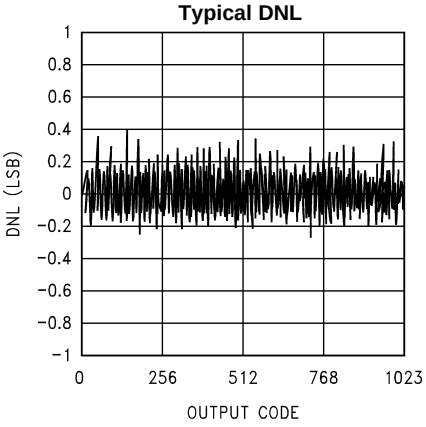



**Figure 12.**

**DNL vs. Supply Voltage**

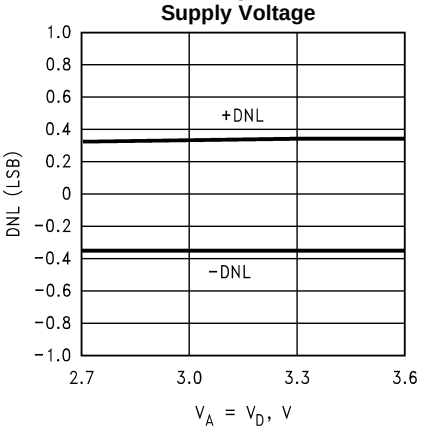



**Figure 13.**

**DNL vs. $V_{REF}$**

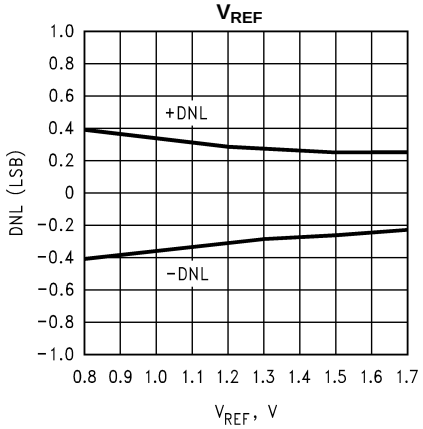



**Figure 14.**

**DNL vs. $f_{CLK}$**

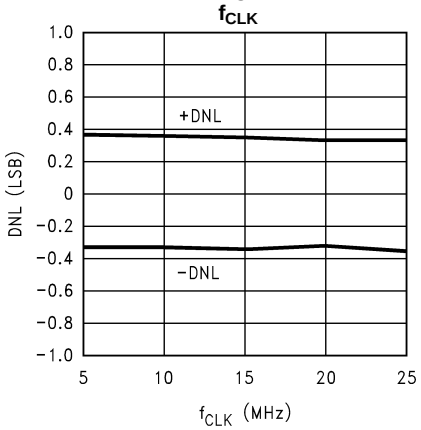



**Figure 15.**

**DNL vs. Clock Duty Cycle**

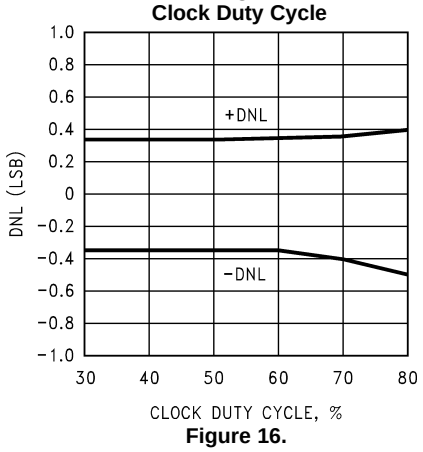



**Figure 16.**

**DNL vs. Temperature**

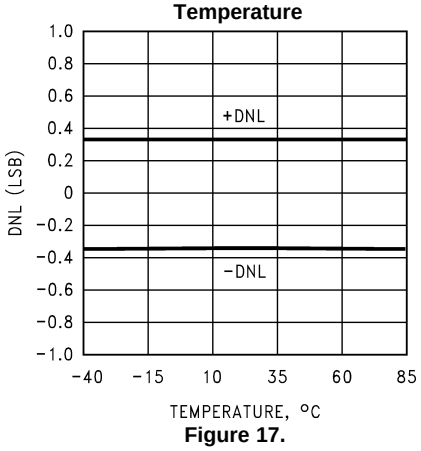



**Figure 17.**

## Typical Performance Characteristics (continued)

$V_A = V_D = V_{DR} = 3.0V$, $f_{CLK}$ = 20 MHz, unless otherwise specified

**SNR vs. Supply Voltage @ $f_{IN}$ = 1 MHz to 9.5 MHz**

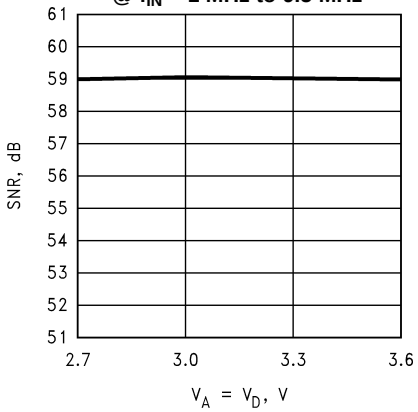



**Figure 18.**

**SNR vs. $V_{REF}$ @ $f_{IN}$ = 4.7 MHz**

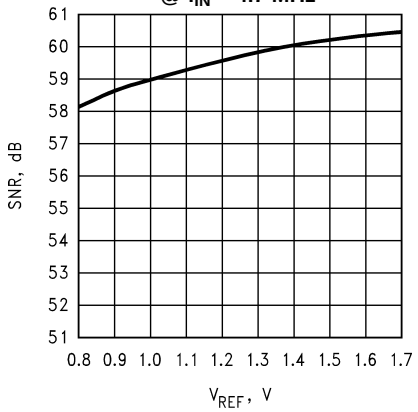



**Figure 19.**

**SNR vs. $f_{CLK}$ @ $f_{IN}$ = 9.5 MHz**

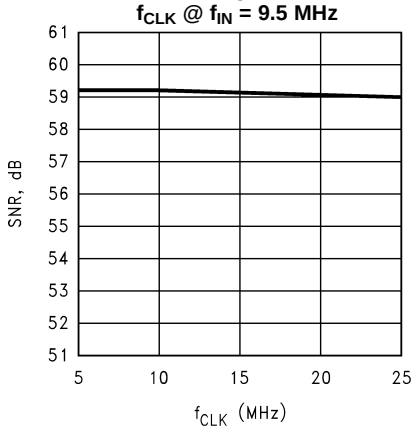



**Figure 20.**

**SNR vs. $f_{IN}$**

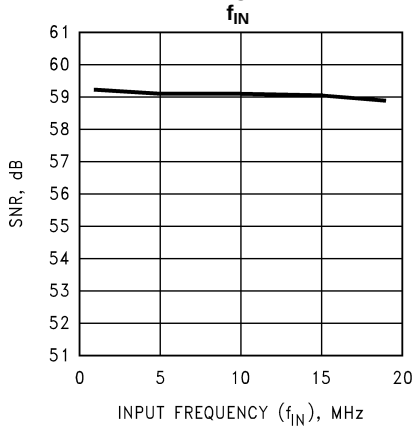



**Figure 21.**

**SNR vs. Clock Duty Cycle @ $f_{IN}$ = 4.7 MHz**

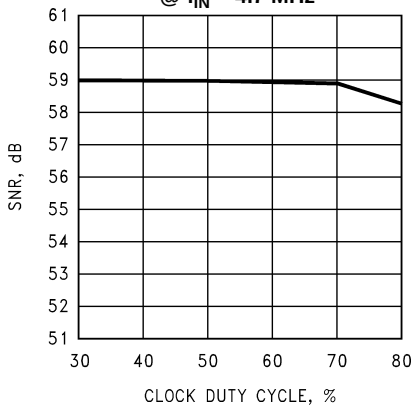



**Figure 22.**

**SNR vs. $V_{DR}$ @ $f_{IN}$ = 9.5 MHz**

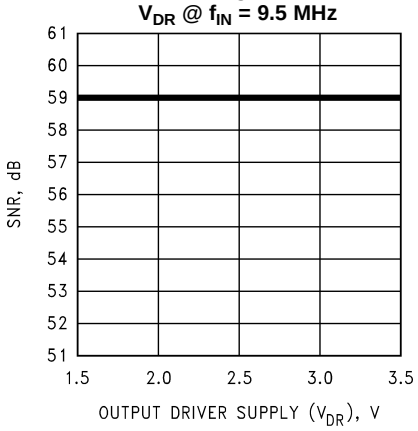



**Figure 23.**

## Typical Performance Characteristics (continued)

$V_A = V_D = V_{DR} = 3.0V$, $f_{CLK}$ = 20 MHz, unless otherwise specified

**SNR vs. $V_{CM}$ @ $f_{IN}$ = 9.5 MHz**

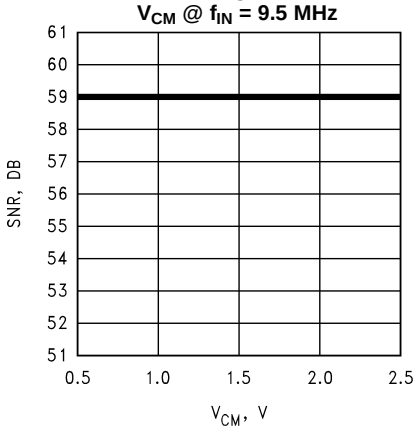



**Figure 24.**

**SNR vs. Temperature @ $f_{IN}$ = 1 MHz to 9.5 MHz**

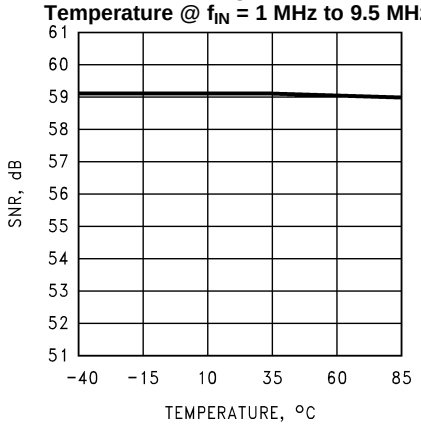



**Figure 25.**

**SINAD & ENOB vs. Supply Voltage @ $f_{IN}$ = 1 MHz to 9.5 MHz**

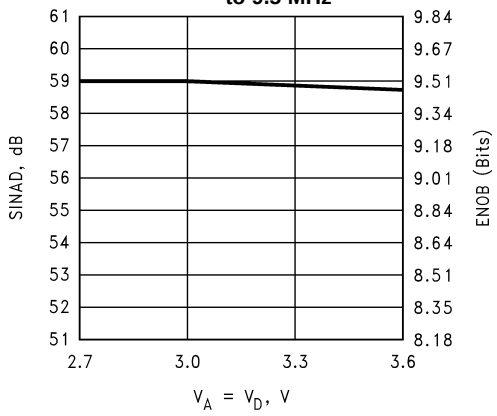



**Figure 26.**

**SINAD & ENOB vs. $V_{REF}$ @ $f_{IN}$ = 4.7 MHz**

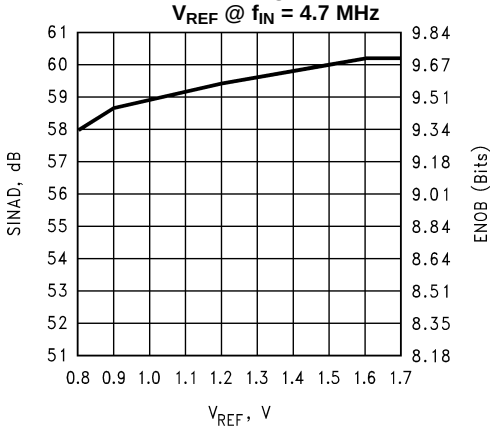



**Figure 27.**

**SINAD & ENOB vs. @ $f_{CLK}$ ($f_{IN}$ = 9.5 MHz)**

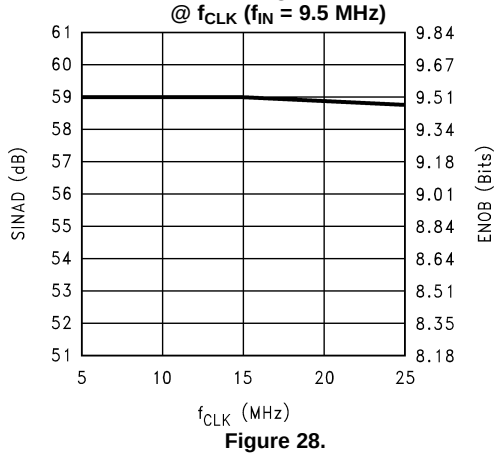



**Figure 28.**

**SINAD & ENOB vs. $f_{IN}$**

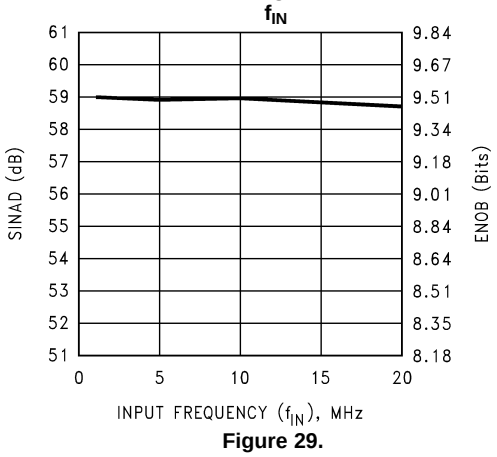



**Figure 29.**

## Typical Performance Characteristics (continued)

$V_A = V_D = V_{DR} = 3.0V$, $f_{CLK}$ = 20 MHz, unless otherwise specified

**SINAD & ENOB vs. Clock Duty Cycle @ $f_{IN}$ = 4.7 MHz**

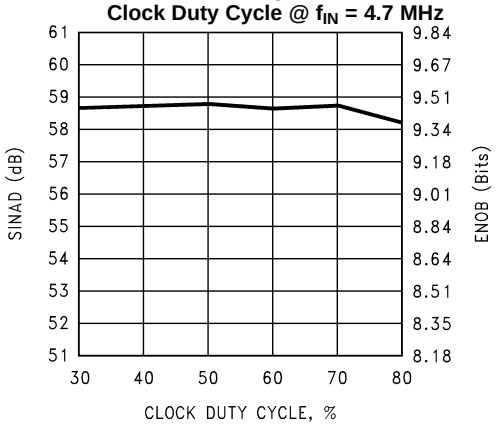



**Figure 30.**

**SINAD & ENOB vs. $V_{DR}$ @ $f_{IN}$ = 9.5 MHz**

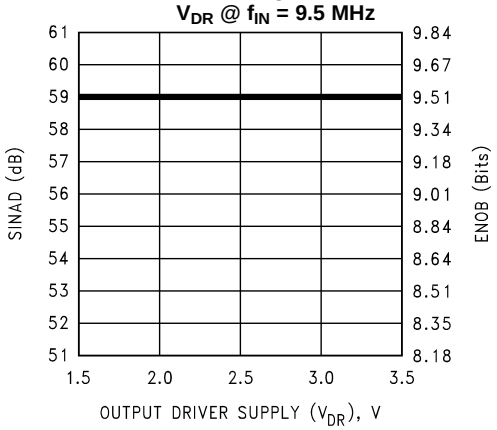



**Figure 31.**

**SINAD & ENOB vs. $V_{CM}$ @ $f_{IN}$ = 9.5 MHz**

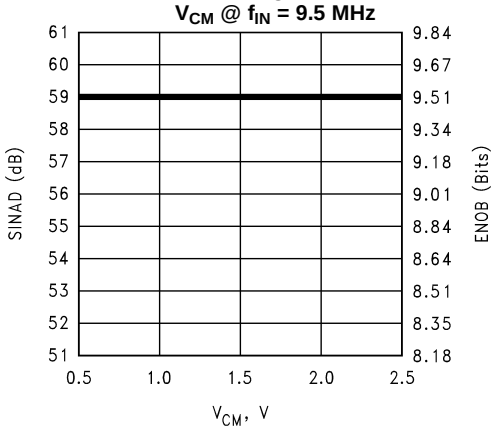



**Figure 32.**

**SINAD & ENOB vs. Temperature @ $f_{IN}$ = 1 MHz to 9.5 MHz**

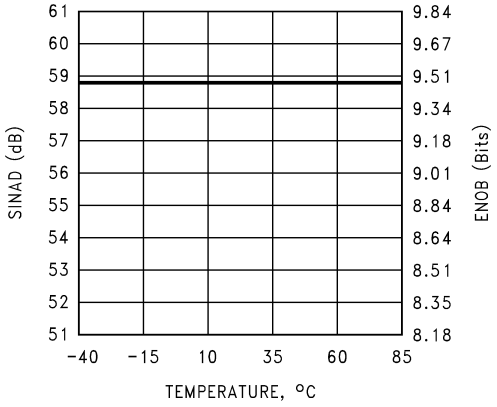



**Figure 33.**

**Distortion vs. Supply Voltage @ $f_{IN}$ = 4.7 MHz**

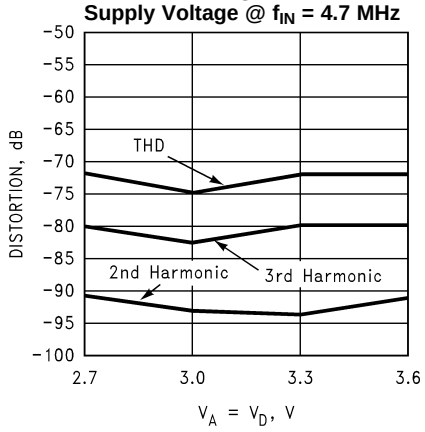



**Figure 34.**

**Distortion vs. $V_{REF}$ @ $f_{IN}$ = 4.7 MHz**

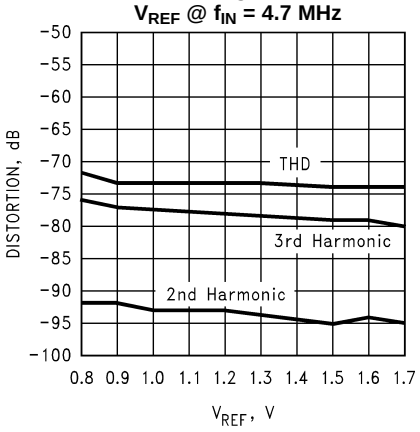



**Figure 35.**

## Typical Performance Characteristics (continued)

$V_A = V_D = V_{DR} = 3.0V$, $f_{CLK} = 20$ MHz, unless otherwise specified

**Distortion vs. $f_{CLK}$ @ $f_{IN}$ = 9.5 MHz**

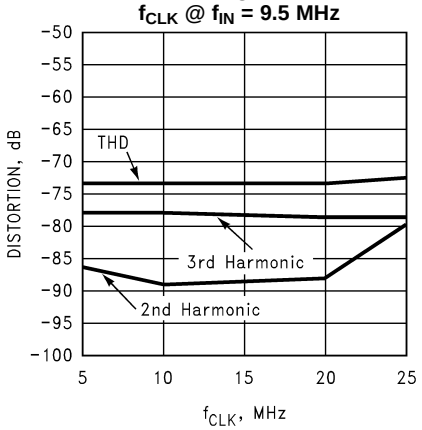



**Figure 36.**

**Distortion vs. $f_{IN}$**

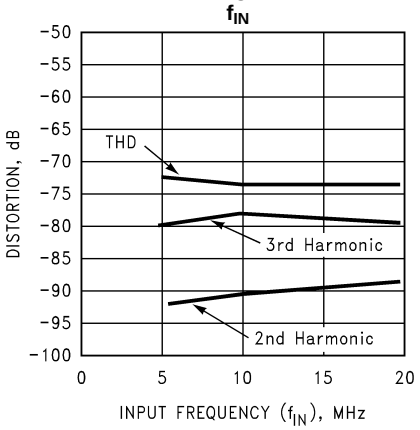



**Figure 37.**

**Distortion vs. Clock Duty Cycle @ $f_{IN}$ = 4.7 MHz**

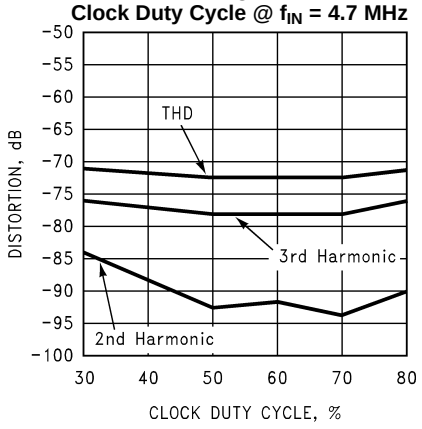



**Figure 38.**

**Distortion vs. $V_{DR}$ @ $f_{IN}$ = 4.7 MHz**

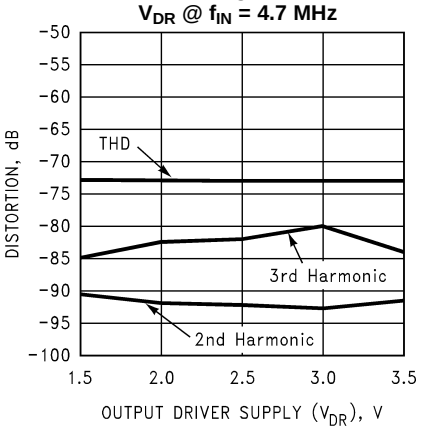



**Figure 39.**

**Distortion vs. $V_{CM}$ @ $f_{IN}$ = 4.7 MHz**

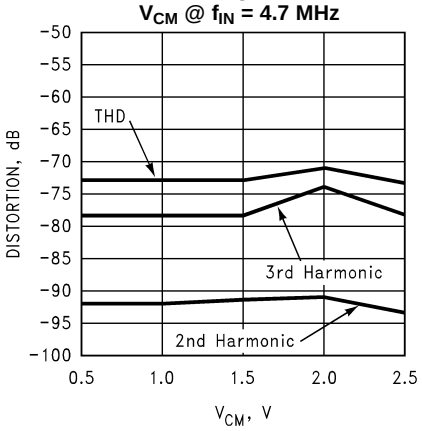



**Figure 40.**

**Distortion vs. Temperature**

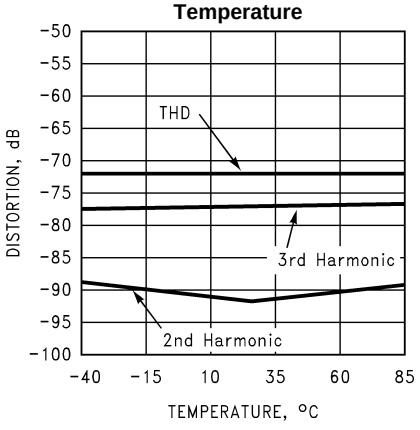



**Figure 41.**

## Typical Performance Characteristics (continued)

$V_A = V_D = V_{DR} = 3.0V$, $f_{CLK} = 20$ MHz, unless otherwise specified

**SFDR vs. Supply Voltage @ $f_{IN}$ = 4.7 MHz**

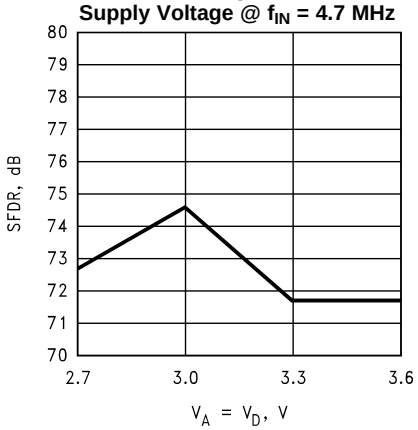



**Figure 42.**

**SFDR vs. $V_{REF}$ @ $f_{IN}$ = 4.7 MHz**

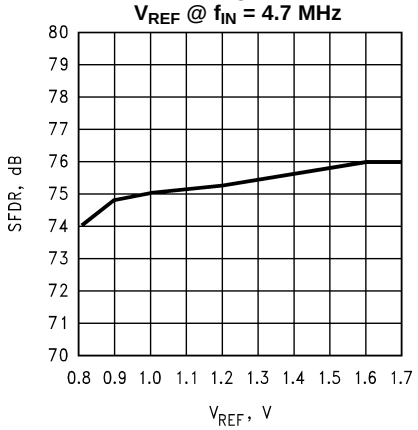



**Figure 43.**

**SFDR vs. $f_{CLK}$ @ $f_{IN}$ = 9.5 MHz**

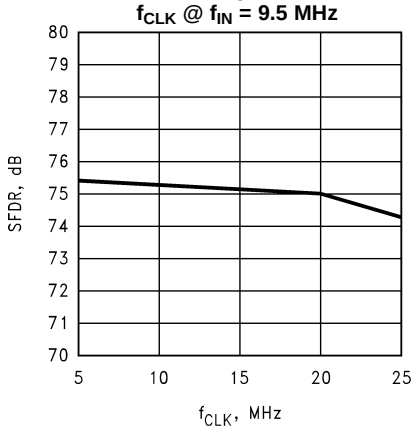



**Figure 44.**

**SFDR vs. $f_{IN}$**

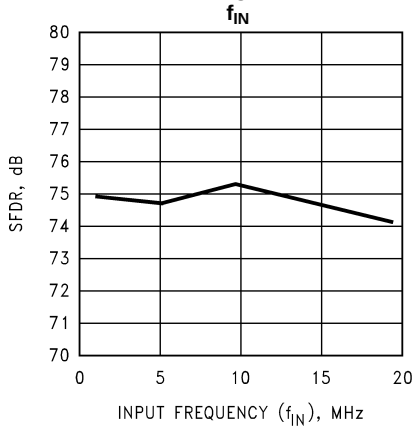



**Figure 45.**

**SFDR vs. Clock Duty Cycle @ $f_{IN}$ = 4.7 MHz**

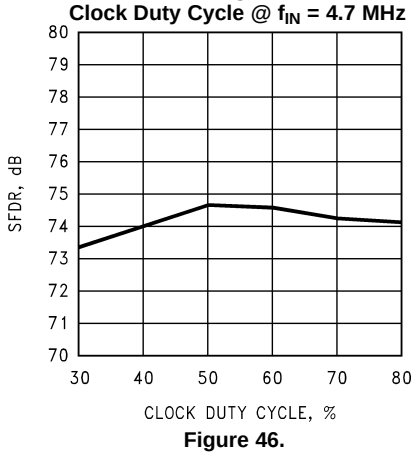



**Figure 46.**

**SFDR vs. $V_{DR}$ @ $f_{IN}$ = 4.7 MHz**

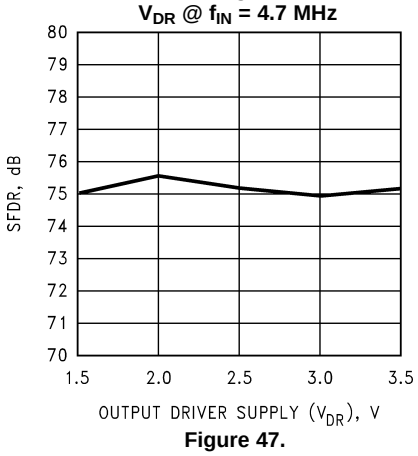



**Figure 47.**

## Typical Performance Characteristics (continued)

$V_A = V_D = V_{DR} = 3.0V$, $f_{CLK}$ = 20 MHz, unless otherwise specified

**SFDR vs. $V_{CM}$ @ $f_{IN}$ = 4.7 MHz**

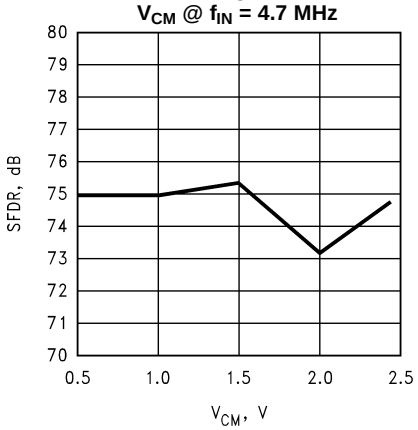



**Figure 48.**

**SFDR vs. Temperature @ $f_{IN}$ = 4.7 MHz**

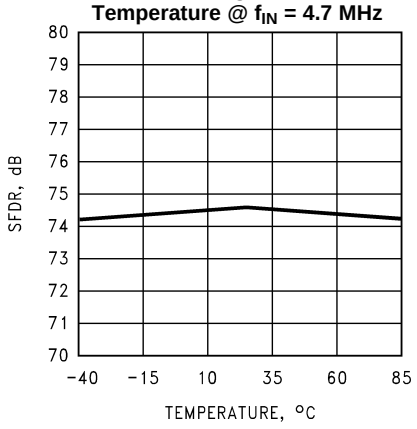



**Figure 49.**

**Crosstalk vs. $f_{IN}$**

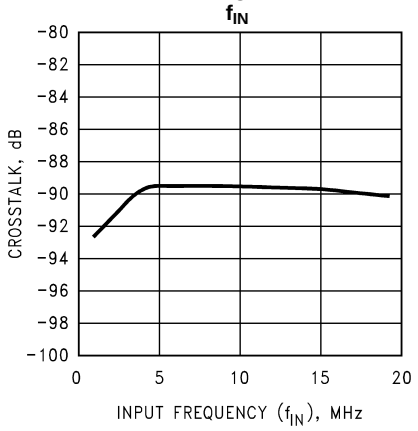



**Figure 50.**

**Crosstalk vs. $V_{DR}$ @ $f_{IN}$ = 4.7 MHz**

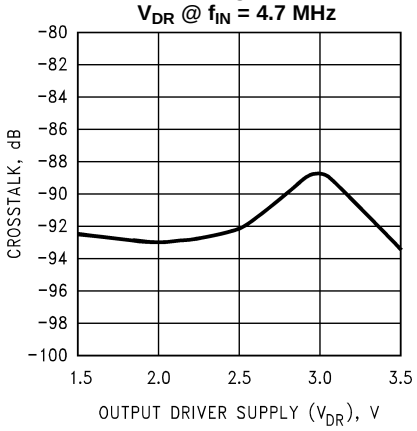



**Figure 51.**

**Crosstalk vs. $V_{CM}$ @ $f_{IN}$ = 4.7 MHz**

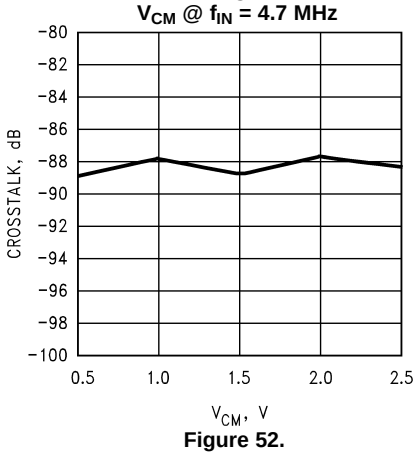



**Figure 52.**

**Crosstalk vs. Temperature**

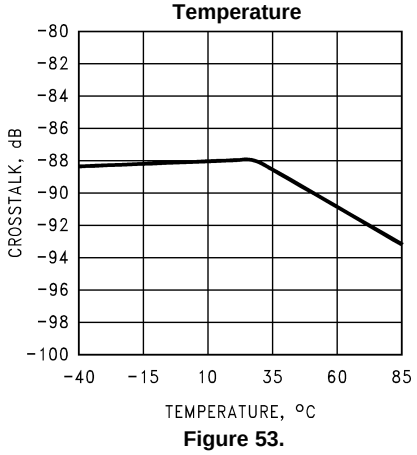



**Figure 53.**

## Typical Performance Characteristics (continued)

$V_A = V_D = V_{DR} = 3.0V$, $f_{CLK} = 20$ MHz, unless otherwise specified

**Power Consumption vs. Temperature**

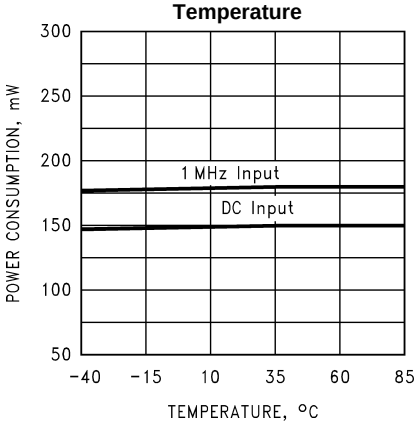



**Figure 54.**

**Spectral Response @ $f_{IN}$ = 1 MHz**

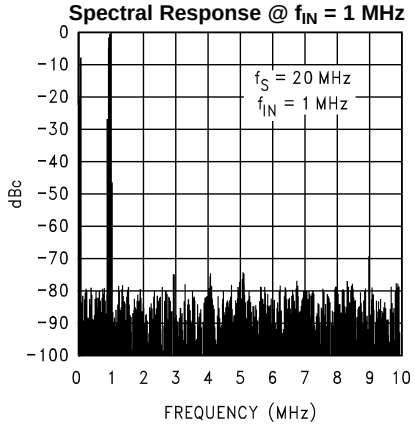



**Figure 55.**

**Spectral Response @ $f_{IN}$ = 4.7 MHz**

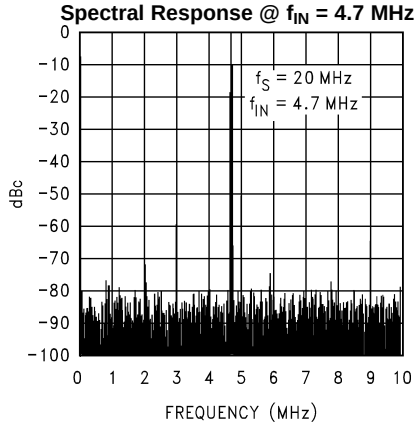



**Figure 56.**

**Spectral Response @ $f_{IN}$ = 9.5 MHz**

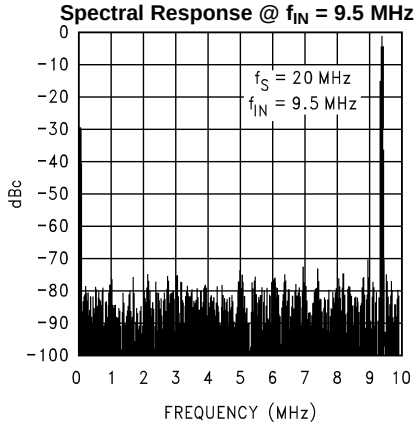



**Figure 57.**

**Spectral Response @ $f_{IN}$ = 21 MHz**

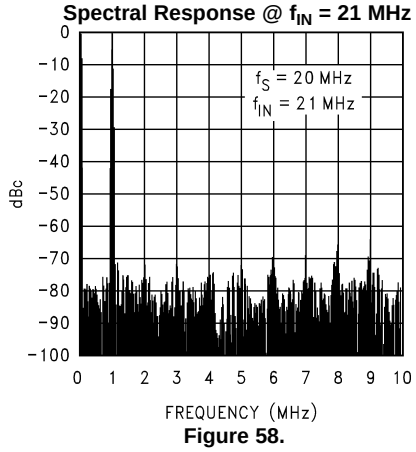



**Figure 58.**

**Spectral Response @ $f_{IN}$ = 49 MHz**

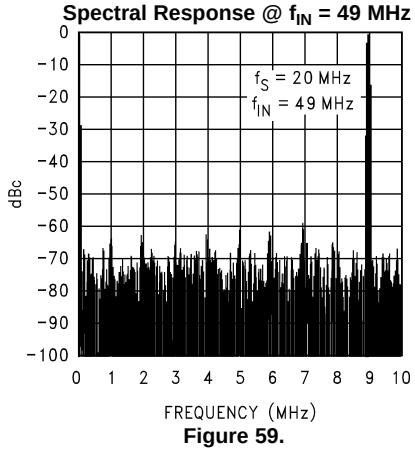



**Figure 59.**

## Typical Performance Characteristics (continued)

$V_A = V_D = V_{DR} = 3.0V$, $f_{CLK} = 20$ MHz, unless otherwise specified

**Spectral Response @ $f_{IN}$ = 99 MHz**

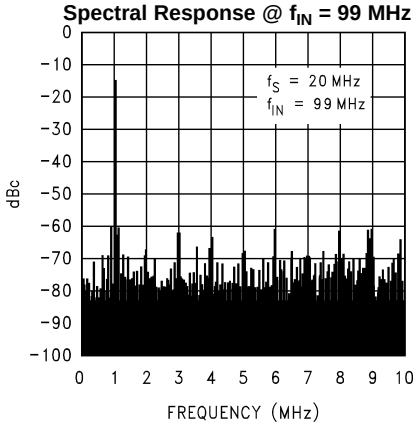



**Figure 60.**

**IMD Response @ $f_{IN}$ = 4.9 MHz, 5.1 MHz**

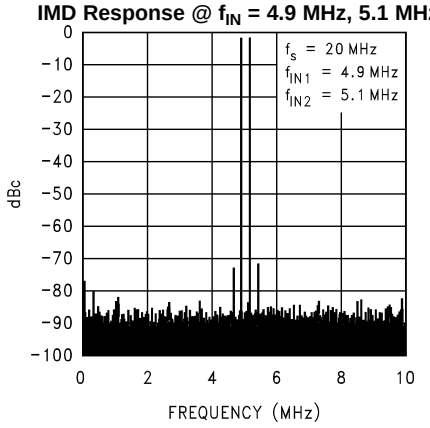



**Figure 61.**

## FUNCTIONAL DESCRIPTION

Using a subranging architecture, the ADC10D020 achieves 9.5 effective bits over the entire Nyquist band at 20 MSPS while consuming just 150 mW. The use of an internal sample-and-hold amplifier (SHA) not only enables this sustained dynamic performance, but also lowers the converter's input capacitance and reduces the number of external components required.

Analog signals at the “I” and “Q” inputs that are within the voltage range set by $V_{REF}$ and the GAIN pin are digitized to ten bits at up to 30 MSPS. $V_{REF}$ has a range of 0.8V to 1.5V providing a differential peak-to-peak input range of 0.8 $V_{P-P}$ to 1.5 $V_{P-P}$ with the GAIN pin at a logic low, or an input range of 1.6 $V_{P-P}$ to 3.0 $V_{P-P}$ with the GAIN pin at a logic high. Differential input voltages less than $-V_{REF}/2$ with the GAIN pin low, or less than $-V_{REF}$ with the GAIN pin high will cause the output word to indicate a negative full scale. Differential input voltages greater than $V_{REF}/2$ with the GAIN pin low, or greater than $V_{REF}$ with the GAIN pin high, will cause the output word to indicate a positive full scale.

Both “I” and “Q” channels are sampled simultaneously on the falling edge of the clock input, while the timing of the data output depends upon the mode of operation.

In the parallel mode, the “I” and “Q” output busses contain the conversion result for their respective inputs. The “I” and “Q” channel data are present and valid at the data output pins $t_{OD}$ after the rising edge of the input clock. In the multiplexed mode, “I” channel data is available at the digital outputs $t_{OD}$ after the rise of the clock edge, while the “Q” channel data is available at the digital outputs $t_{OD}$ after the fall of the clock. However, a delayed I/Q output signal should be used to latch the output for best, most consistent results.

Data latency in the parallel mode is 2.5 clock cycles. In the multiplexed mode data latency is 2.5 clock cycles for the “I” channel and 3.0 clock cycles for the “Q” channel. The ADC10D020 will convert as long as the clock signal is present and the PD and STBY pins are low.

Throughout this discussion, $V_{CM}$ refers to the Common Mode input voltage of the ADC10D020 while $V_{CMO}$ refers to its Common Mode output voltage.

## Applications Information

### THE ANALOG SIGNAL INPUTS

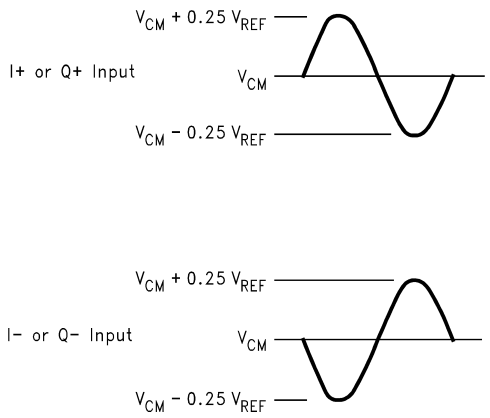
Each of the analog inputs of the ADC10D020 consists of a switch (transmission gate) followed by a switched capacitor amplifier. The capacitance seen at each input pin changes with the clock level, appearing as about 3 pF when the clock is low, and about 6 pF when the clock is high. A switched capacitance is harder to drive than is a larger, fixed capacitance.

The CLC409 and the CLC428 dual op amp have been found to be a good amplifiers to drive the ADC10D020 because of their wide bandwidth and low distortion. They also have good Differential Gain and Differential Phase performance.

Care should be taken to avoid driving the inputs beyond the supply rails, even momentarily, as during power-up.

The ADC10D020 is designed for differential input signals for best performance. With a 1.0V reference and the GAIN pin at a logic low, differential input signals up to 1.0 $V_{P-P}$ are digitized. See Figure 62. For differential signals, the input common mode is expected to be about 1.5V, but the inputs are not sensitive to the common-mode voltage and can be anywhere within the supply rails (ground to $V_A$) with little or no performance degradation, as long as the signal swing at the individual input pins is no more than 300 mV beyond the supply rails. For single ended drive, operate the ADC10D020 with the GAIN pin at a logic low, connect one pin of the input pair to 1.5V ($V_{CM}$) and drive the other pin of the input pair with 1.0 $V_{P-P}$ centered around 1.5V.

Because of the larger signal swing at one input for single-ended operation, distortion performance will not be as good as with a differential input signal. Alternatively, single-ended to differential conversion with a transformer provides a quick. easy solution for those applications not requiring response to dc and low frequencies. See Figure 63. The 36Ω resistors and 110 pF capacitor values are chosen to provide a cutoff frequency near the clock frequency to compensate for the effects of input sampling. A lower time constant should be used for undersampling applications.




The ADC10D020 is designed for use with differential signals of 1.0 $V_{P-P}$ with a common mode voltage of 1.5V. The signal swing should not cause any pin to experience a swing more than 300 mV beyond the supply rails.

**Figure 62.**

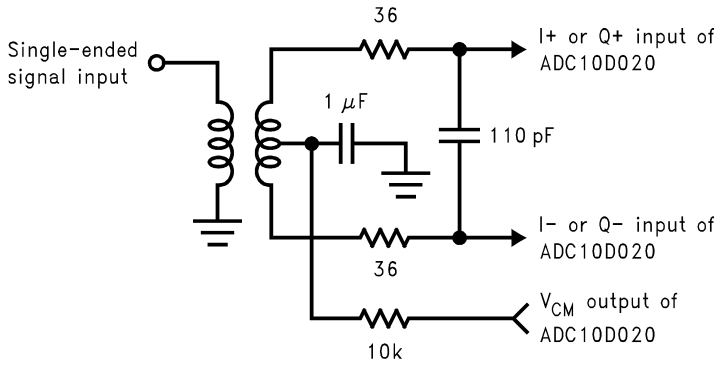
## REFERENCE INPUTS

The $V_{RP}$ and $V_{RN}$ pins should each be bypassed with a 5 µF (or larger) tantalum or electrolytic capacitor and a 0.1 µF ceramic capacitor. Use these pins only for bypassing. DO NOT connect anything else to these pins.

Figure 64 shows a simple reference biasing scheme with minimal components. While this circuit will suffice for many applications, the value of the reference voltage will depend upon the supply voltage.

The circuit of Figure 65 is an improvement over the circuit of Figure 64 because the reference voltage is independent of supply voltage. This reduces problems of reference voltage variability. The reference voltage at the $V_{REF}$ pin should be bypassed to AGND with a 5 µF (or larger) tantalum or electrolytic capacitor and a 0.1 µF ceramic capacitor.

The circuit of Figure 66 may be used if it is desired to obtain a precise reference voltage not available with a fixed reference source. The 240Ω and 1k resistors can be replaced with a potentiometer, if desired.




Use of an input transformer for single-ended to differential conversion can simplify circuit design for single-ended signals.

**Figure 63.**

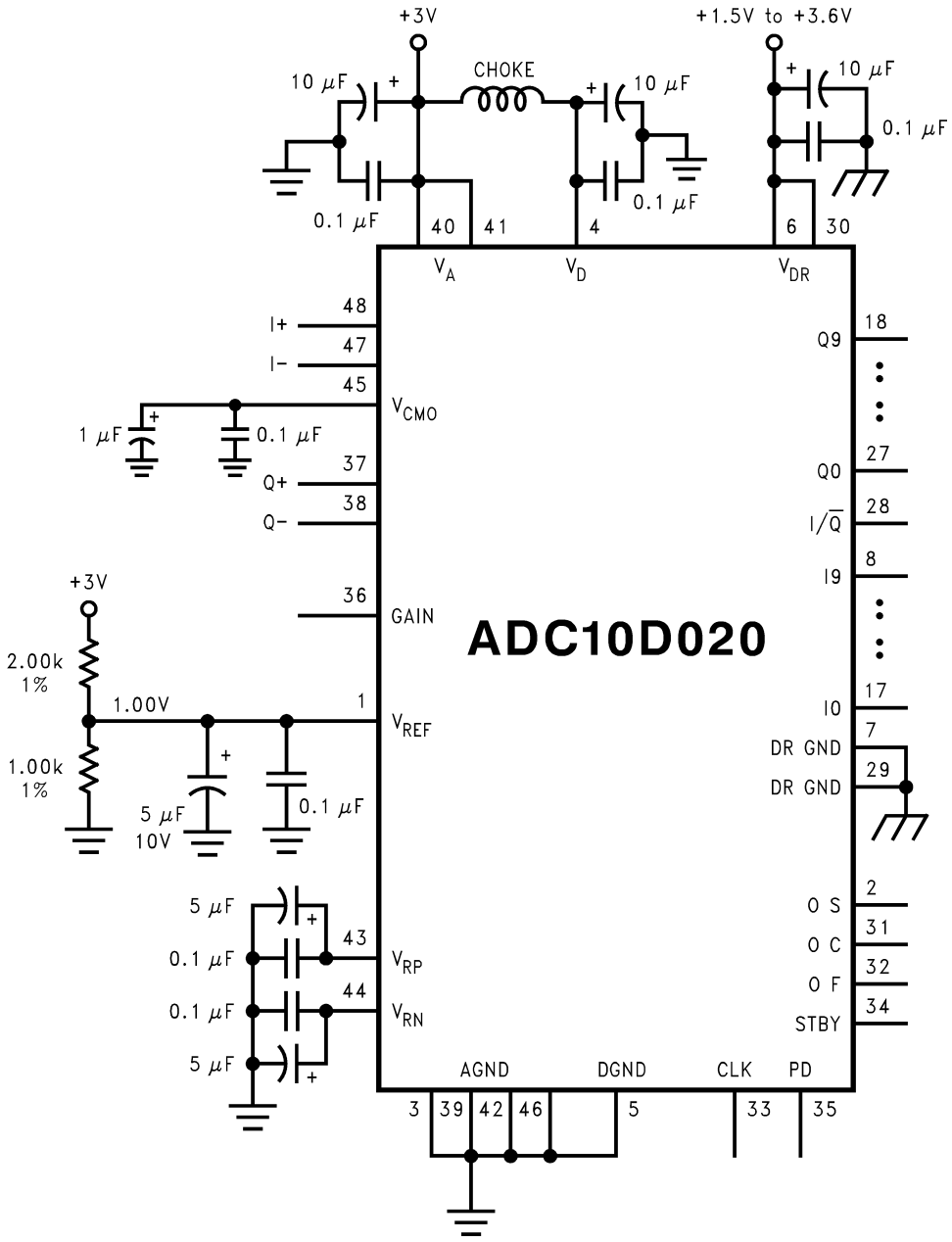



**Figure 64. Simple Reference Biasing**

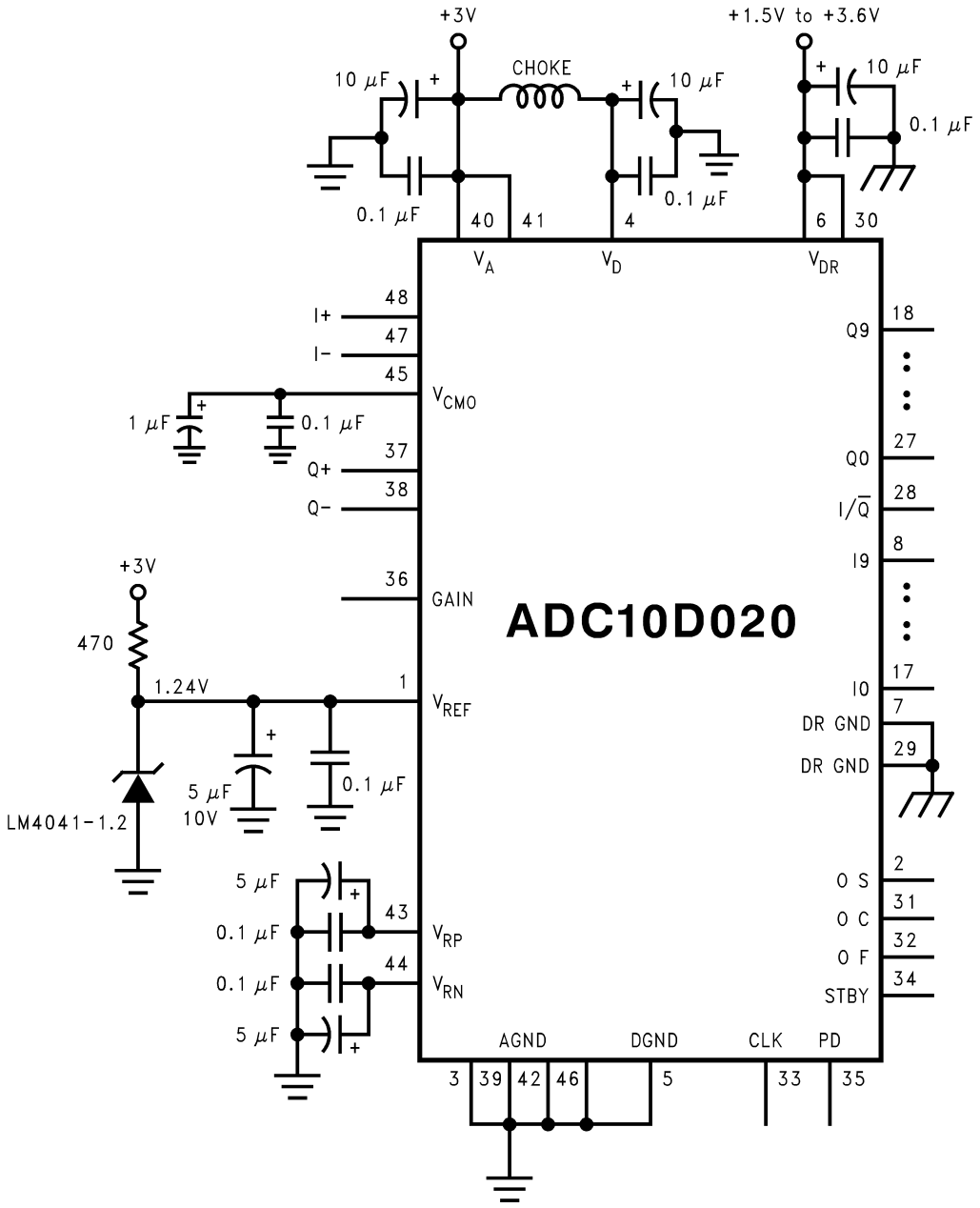



**Figure 65. Improved Low Component Count Reference Biasing**

The $V_{CMO}$ output can be used as the ADC reference source as long as care is taken to prevent excessive loading of this pin. However, the $V_{CMO}$ output was not designed to be a precision reference and has more variability than does a precision reference. Refer to $V_{CMO}$, Common Mode Voltage Output, in Electrical Characteristics. Since the reference input of the ADC10D020 is buffered, there is virtually no loading on the $V_{CMO}$ output by the $V_{REF}$ pin. While the ADC10D020 will work with a 1.5V reference voltage, it is fully specified for a 1.0V reference. To use the $V_{CMO}$ for a reference voltage at 1.0V, the 1.5V $V_{CMO}$ output needs to be divided down. The divider resistor values need to be carefully chosen to prevent excessive $V_{CMO}$ loading. See Figure 67. While the average temperature coefficient of $V_{CMO}$ is 20 ppm/°C, that temperature coefficient can be broken down to a typical 50 ppm/°C between −40°C and +25°C and a typical −12 ppm/°C between +25°C and +85°C.

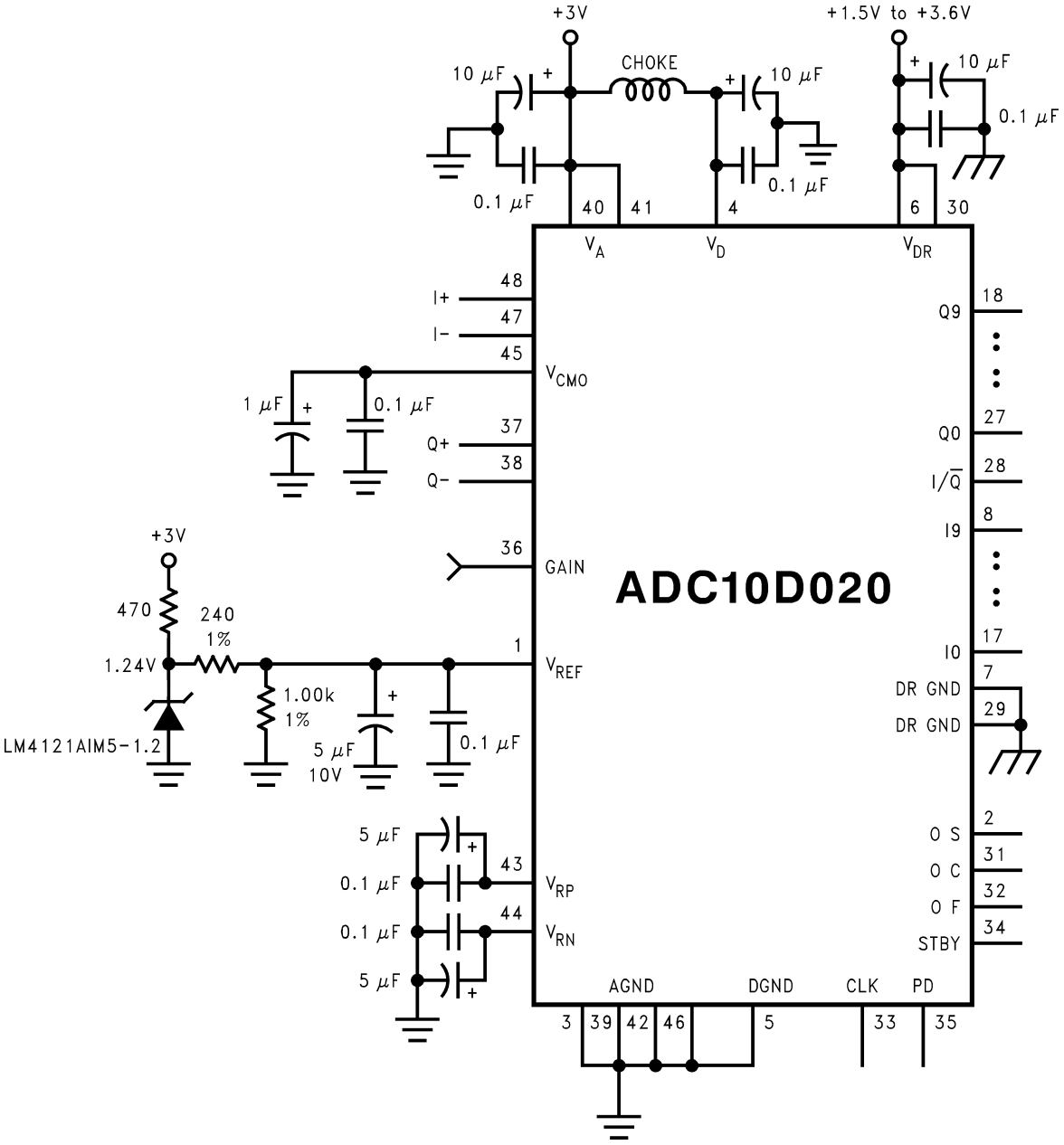
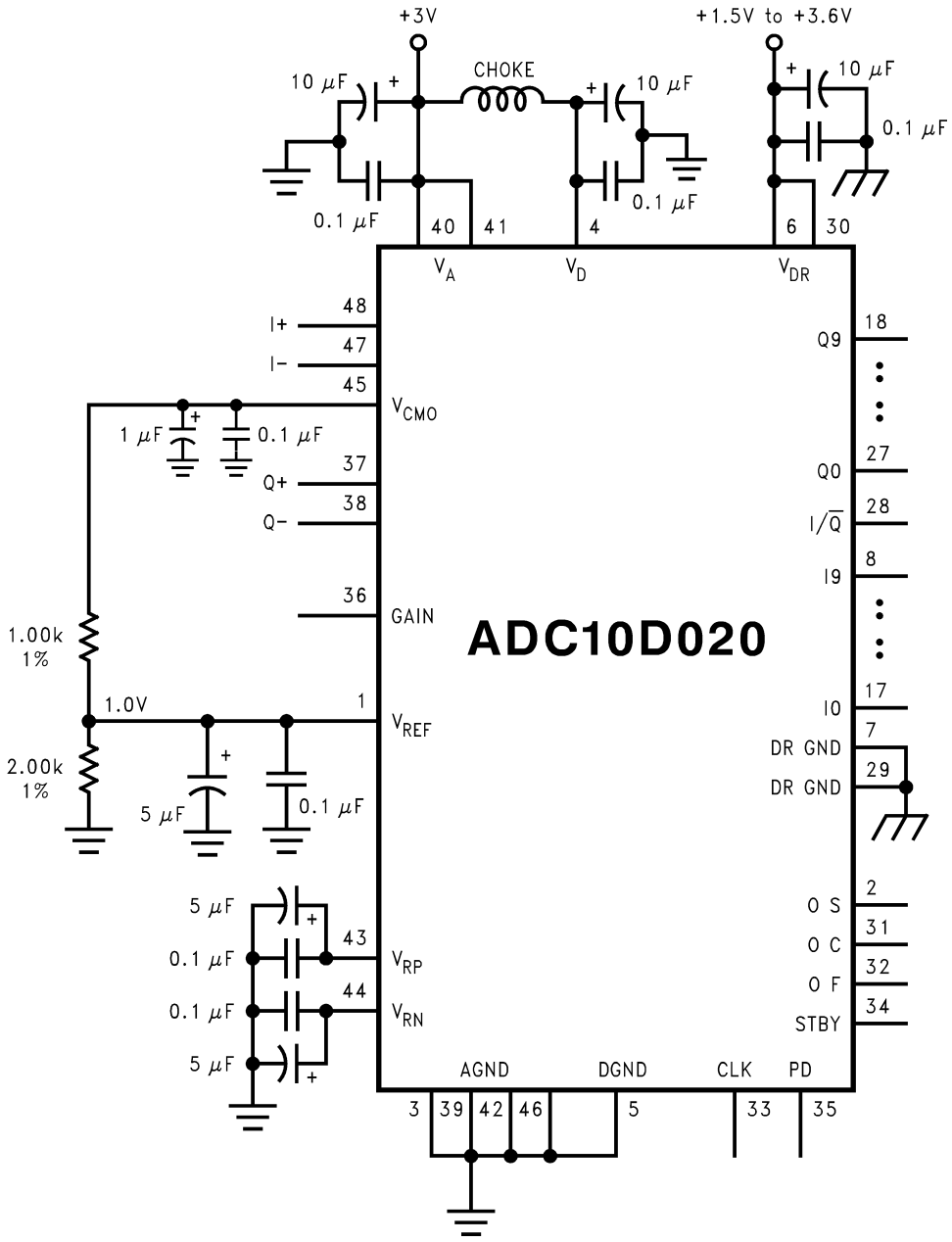



**Figure 66. Setting An Accurate Reference Voltage**




The $V_{CMO}$ output pin may be used as an internal reference source if its output is divided down and not loaded excessively.

**Figure 67.**

### *REFERENCE VOLTAGE*

The reference voltage should be within the range specified in the Operating Ratings (0.8V to 1.5V). A reference voltage that is too low could result in a noise performance that is less than desired because the quantization level falls below other noise sources. On the other hand, a reference voltage that is too high means that an input signal that produces a full scale output uses such a large input range that the input stage is less linear, resulting in a degradation of distortion performance. Also, for large reference voltages, the internal ladder buffer runs out of head-room, leading to a reduction of gain in that buffer and causing gain error degradation.

The Reference bypass pins $V_{RP}$ and $V_{RN}$ are output compensated and should each be bypassed with a parallel combination of a 5 µF (minimum) and 0.1 µF capacitors.

As mentioned in the previous section, the $V_{CMO}$ output can be used as the ADC reference.

### *$V_{CMO}$ OUTPUT*

The $V_{CMO}$ output pin is intended to provide a common mode bias for the differential input pins of the ADC10D020. It can also be used as a voltage reference source. Care should be taken, however, to avoid loading this pin with more than 1 mA. A load greater than this could result in degraded long term and temperature stability of this voltage. The $V_{CMO}$ pin is output compensated and should be bypassed with a 2 µF/0.1 µF combination, minimum. See REFERENCE INPUTS for more information on using the $V_{CMO}$ output as a reference source.

## DIGITAL INPUT PINS

The seven digital input pins are used to control the function of the ADC10D020.

### *CLOCK (CLK) INPUT*

The clock (CLK) input is common to both A/D converters. This pin is CMOS/LVTTL compatible with a threshold of about $V_A/2$. Although the ADC10D020 is tested and its performance is specified with a 20 MHz clock, it typically will function well with low-jitter clock frequencies from 1 MHz to 30 MHz. The clock source should be series terminated to match the source impedance with the characteristic impedance, $Z_O$, of the clock line and the ADC clock pin should be AC terminated, near the clock input, with a series RC to ground. The resistor value should equal the characteristic impedance, $Z_O$, of the clock line and the capacitor should have a value such that $C \times Z_O \geq 4 \times t_{PD}$, where $t_{PD}$ is the time of propagation of the clock signal from its source to the ADC clock pin. The typical propagation rate on a board of FR4 material is about 150 ps/inch. The rise and fall times of the clock supplied to the ADC clock pin should be no more than 4 ns. The analog inputs I = (I+) – (I−) and Q = (Q+) – (Q−) are simultaneously sampled on the falling edge of this input to ensure the best possible aperture delay match between the two channels.

### *OUTPUT BUS SELECT (OS) PIN*

The Output Bus Select (OS) pin determines whether the ADC10D020 is in the parallel or multiplexed mode of operation. A logic high at this pin puts the device into the parallel mode of operation where “I” and “Q” data appear at their respective output buses. A logic low at this pin puts the device into the multiplexed mode of operation where the “I” and “Q” data are multiplexed onto the “I” output bus and the “Q” output lines all remain at a logic low.

### *OFFSET CORRECT (OC) PIN*

The Offset Correct (OC) pin is used to initiate an offset correction sequence. This procedure should be done after power up and need not be performed again unless power to the ADC10D020 is interrupted. An independent offset correction sequence for each converter is initiated when there is a low-to-high transition at the OC pin. This sequence takes 34 clock cycles to complete, during which time 32 conversions are taken and averaged. The result is subtracted from subsequent conversions. Because the offset correction is performed digitally at the output of the ADC, the output range of the ADC is reduced by the offset amount.

Upon power up, the offset correction coefficients are set to zero. The Electrical Table indicates the Offset Error with and without performing an offset correction.

Each input pair should have a 0V differential voltage value during this entire 34 clock period, but the “I” and “Q” input common mode voltages do not have to be equal to each other. Because of the uncertainty as to exactly when the correction sequence starts, it is best to allow 35 clock periods for this sequence.

### *OUTPUT FORMAT (OF) PIN*

The Output Format (OF) pin provides a choice of offset binary or 2's complement output formatting. With this pin at a logic low, the output format is offset binary. With this pin at a logic high, the output format is 2's complement.

### *STANDBY (STBY) PIN*

The Standby (STBY) pin may be used to put the ADC10D020 into a low power mode where it consumes just 27 mW and can quickly be brought to full operation. In this mode, most of the ADC10D020 is powered down, but the bias and reference circuitry remained powered up to allow for a faster recovery from a low power standby condition. The device operates normally with a logic low on this and the PD pins.

While in the Standby mode the data outputs contain the results of the last conversion before going into this Mode.

### *POWER DOWN (PD) PIN*

The Power Down (PD) pin puts the device into a low-power "sleep" state where it consumes less than 1 mW when the PD pin is at a logic high. Power consumption is reduced more when the PD pin is high than when the STBY pin is high, but recovery to full operation is much quicker from the standby state than it is from the power down state. When the STBY and PD pins are both high, the ADC10D020 is in the power down mode.

While in the Power Down mode the data outputs contain the results of the last conversion before going into this mode.

### *GAIN PIN*

The GAIN pin sets the internal signal gain of the "I" and "Q" inputs. With this pin at a logic low, the full scale differential peak-to-peak input signal is equal to $V_{REF}$. With the GAIN pin at a logic high, the full scale differential peak-to-peak input signal is equal to 2 times $V_{REF}$.

## INPUT/OUTPUT RELATIONSHIP ALTERNATIVES

The GAIN pin of the ADC10D020 offers input range selection, while the OF pin offers a choice of offset binary or 2's complement output formatting.

The relationship between the GAIN, OF, analog inputs and the output code are as defined in Table 1. Keep in mind that the input signals must not exceed the power supply rails.

**Table 1. ADC10D020 Input/Output Relationships**

| GAIN | OF | I+ / Q+ | I− / Q− | Output Code |
|---|---|---|---|---|
| 0 | 0 | $V_{CM}$ + 0.25*$V_{REF}$ | $V_{CM}$ − 0.25*$V_{REF}$ | 11 1111 1111 |
| 0 | 0 | $V_{CM}$ | $V_{CM}$ | 10 0000 0000 |
| 0 | 0 | $V_{CM}$ − 0.25*$V_{REF}$ | $V_{CM}$ + 0.25*$V_{REF}$ | 00 0000 0000 |
| 0 | 1 | $V_{CM}$ + 0.25*$V_{REF}$ | $V_{CM}$ − 0.25*$V_{REF}$ | 01 1111 1111 |
| 0 | 1 | $V_{CM}$ | $V_{CM}$ | 00 0000 0000 |
| 0 | 1 | $V_{CM}$ − 0.25*$V_{REF}$ | $V_{CM}$ + 0.25*$V_{REF}$ | 10 0000 0000 |
| 1 | 0 | $V_{CM}$ + 0.5*$V_{REF}$ | $V_{CM}$ − 0.5*$V_{REF}$ | 11 1111 1111 |
| 1 | 0 | $V_{CM}$ | $V_{CM}$ | 10 0000 0000 |
| 1 | 0 | $V_{CM}$ − 0.5*$V_{REF}$ | $V_{CM}$ + 0.5*$V_{REF}$ | 00 0000 0000 |
| 1 | 1 | $V_{CM}$ + 0.5*$V_{REF}$ | $V_{CM}$ − 0.5*$V_{REF}$ | 01 1111 1111 |
| 1 | 1 | $V_{CM}$ | $V_{CM}$ | 00 0000 0000 |
| 1 | 1 | $V_{CM}$ − 0.5*$V_{REF}$ | $V_{CM}$ + 0.5*$V_{REF}$ | 10 0000 0000 |

## POWER SUPPLY CONSIDERATIONS

A/D converters draw sufficient transient current to corrupt their own power supplies if not adequately bypassed. A 10 µF to 50 µF tantalum or aluminum electrolytic capacitor should be placed within half an inch (1.2 centimeters) of the A/D power pins, with a 0.1 µF ceramic chip capacitor placed as close as possible to each of the converter's power supply pins. Leadless chip capacitors are preferred because they have low lead inductance.

While a single voltage source should be used for the analog and digital supplies of the ADC10D020, these supply pins should be well isolated from each other to prevent any digital noise from being coupled to the analog power pins. A choke is recommended between the $V_A$ and $V_D$ supply lines. $V_{DR}$ should have a separate supply from $V_A$ and $V_D$ to avoid noise coupling.

The $V_{DR}$ pins are completely isolated from the other supply pins. Because of this isolation, a separate supply can be used for these pins. This $V_{DR}$ supply can be significantly lower than the three volts used for the other supplies, easing the interface to lower voltage digital systems. Using a lower voltage for this supply can also reduce the power consumption and noise associated with the output drivers.

The converter digital supply should **not** be the supply that is used for other digital circuitry on the board. It should be the same supply used for the ADC10D020 analog supply.

As is the case with all high speed converters, the ADC10D020 should be assumed to have little high frequency power supply rejection. A clean analog power source should be used.

No pin should ever have a voltage on it that is more than 300 mV in excess of the supply voltages or below ground, not even on a transient basis. This can be a problem upon application of power to a circuit and upon turn off of the power source. Be sure that the supplies to circuits driving the CLK, or any other digital or analog inputs do not come up any faster than does the voltage at the ADC10D020 power pins.

## LAYOUT AND GROUNDING

Proper routing of all signals and proper ground techniques are essential to ensure accurate conversion. Separate analog and digital ground planes may be used if adequate care is taken with signal routing, but may result in EMI/RFI. A single ground plane with proper component placement will yield good results while minimizing EMI/RFI.

Analog and digital ground current paths should not coincide with each other as the common impedance will cause digital noise to be added to analog signals. Accordingly, traces carrying digital signals should be kept as far away from traces carrying analog signals as is possible. Power should be routed with traces rather than the use of a power plane. The analog and digital power traces should be kept well away from each other. All power to the ADC10D020, except $V_{DR}$, should be considered analog. The DR GND pin should be considered a digital ground and not be connected to the ground plane in close proximity with the other ground pins of the ADC10D020.

Each bypass capacitor should be located as close to the appropriate converter pin as possible and connected to the pin and the appropriate ground plane with short traces. The analog input should be isolated from noisy signal traces to avoid coupling of spurious signals into the input. Any external component (e.g., a filter capacitor) connected between the converter's input and ground should be connected to a very clean point in the ground return.

The clock line should be properly terminated, as discussed in CLOCK (CLK) INPUT, and be as short as possible.

Figure 68 gives an example of a suitable layout and bypass capacitor placement. All analog circuitry (input amplifiers, filters, reference components, etc.) and interconnections should be placed in an area reserved for analog circuitry. All digital circuitry and I/O lines should be placed in an area reserved for digital circuitry. Violating these rules can result in digital noise getting into the analog circuitry, which will degrade accuracy and dynamic performance (THD, SNR, SINAD).

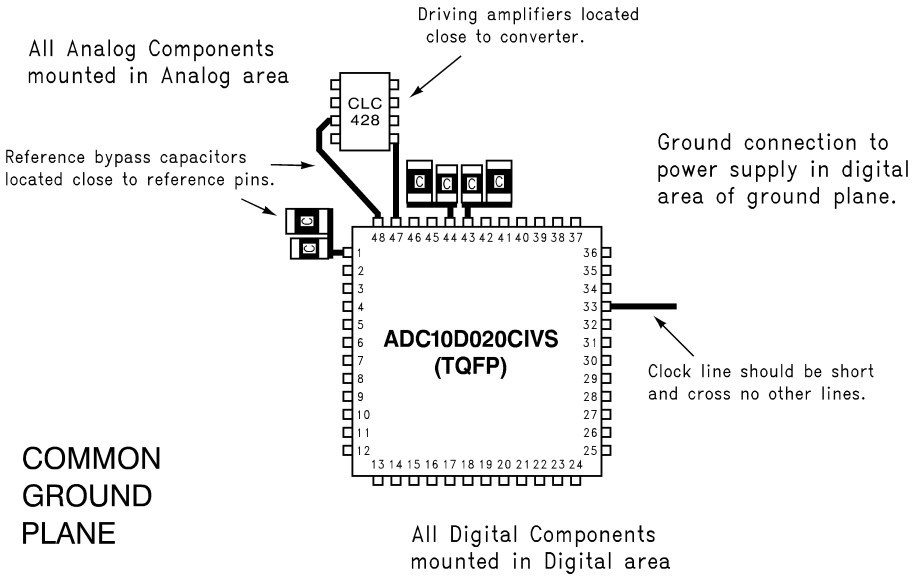



**Figure 68. An Acceptable Layout Pattern**

## DYNAMIC PERFORMANCE

The ADC10D020 is a.c. tested and its dynamic performance is ensured. To meet the published specifications, the clock source driving the CLK input must be free of jitter. For best dynamic performance, isolating the ADC clock from any digital circuitry should be done with adequate buffers, as with a clock tree. See Figure 69.

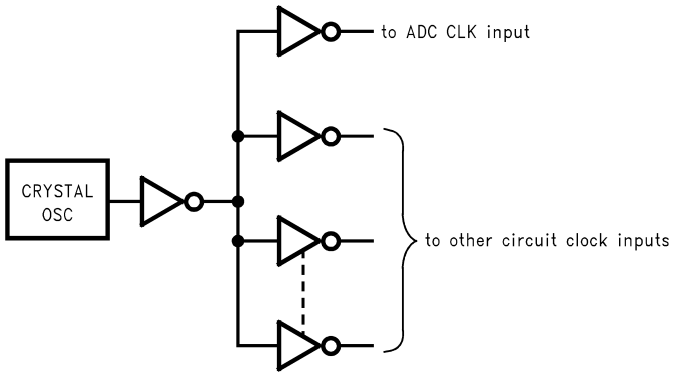



**Figure 69. Isolating the ADC Clock from Digital Circuitry**

## COMMON APPLICATION PITFALLS

**Driving the inputs (analog or digital) beyond the power supply rails.** For proper operation, no input should go more than 300 mV beyond the supply pins. Exceeding these limits on even a transient basis can cause faulty or erratic operation. It is not uncommon for high speed digital circuits (e.g., 74F and 74AC devices) to exhibit overshoot and undershoot that goes a few hundred millivolts beyond the supply rails. A resistor of 50Ω to 100Ω in series with the offending digital input, close to the source, will usually eliminate the problem.

Care should be taken not to overdrive the inputs of the ADC10D020 (or any device) with a device that is powered from supplies outside the range of the ADC10D020 supply. Such practice may lead to conversion inaccuracies and even to device damage.

**Attempting to drive a high capacitance digital data bus.** The more capacitance the output drivers have to charge for each conversion, the more instantaneous digital current is required from $V_{DR}$ and DR GND. These large charging current spikes can couple into the analog section, degrading dynamic performance. Adequate bypassing and attention to board layout will reduce this problem. Buffering the digital data outputs (with a 74ACTQ841, for example) may be necessary if the data bus to be driven is heavily loaded. Dynamic performance can also be improved by adding series resistors of 47Ω to 56Ω at each digital output, close to the ADC output pins.

**Using a clock source with excessive jitter.** This will cause the sampling interval to vary, causing excessive output noise and a reduction in SNR and SINAD performance. The use of simple gates with RC timing as a clock source is generally inadequate.

**Using the same voltage source for $V_D$ and external digital logic.** As mentioned in CLOCK (CLK) INPUT, $V_D$ should use the same power source used by $V_A$ and other analog components, but should be decoupled from $V_A$.

## REVISION HISTORY

| Changes from Revision C (March 2013) to Revision D | Page |
|---|---|
| • Changed layout of National Data Sheet to TI format | 32 |

## PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|---|---|---|---|---|---|---|---|---|---|---|---|
| ADC10D020CIVS/NOPB | ACTIVE | TQFP | PFB | 48 | 250 | RoHS & Green | SN | Level-3-260C-168 HR | -40 to 85 | 10D020 CIVS | Samples |

(1) The marketing status values are defined as follows:
**ACTIVE:** Product device recommended for new designs.
**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.
**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

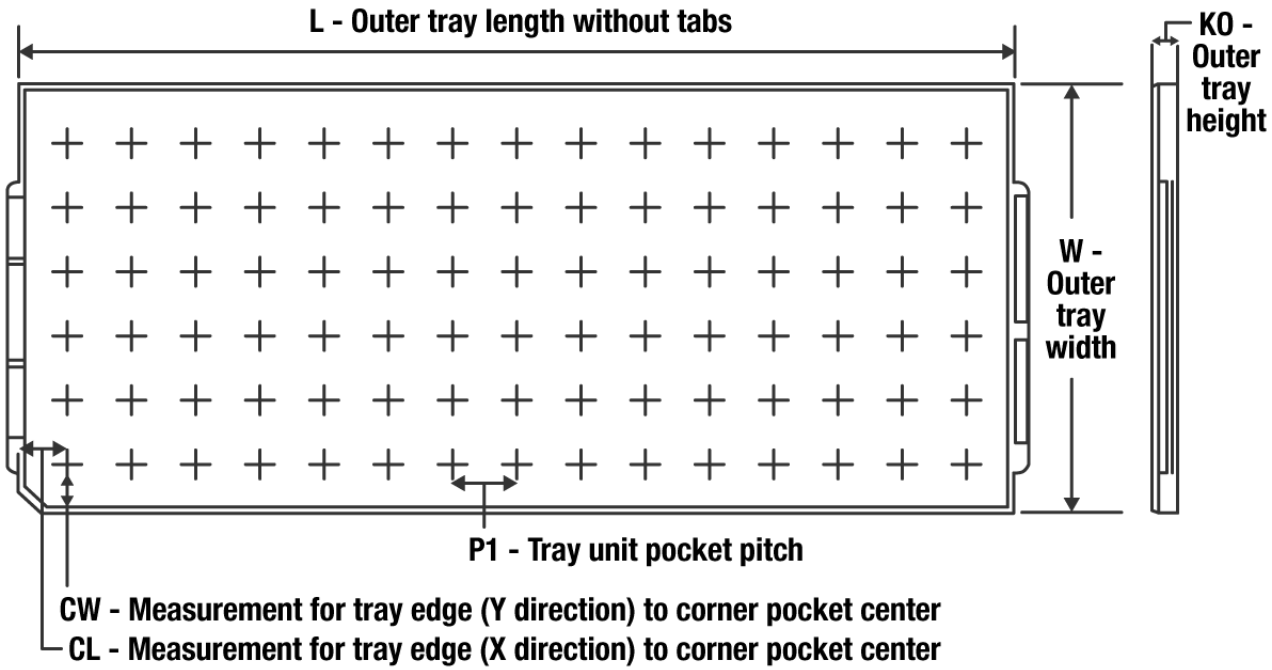
(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

## TRAY



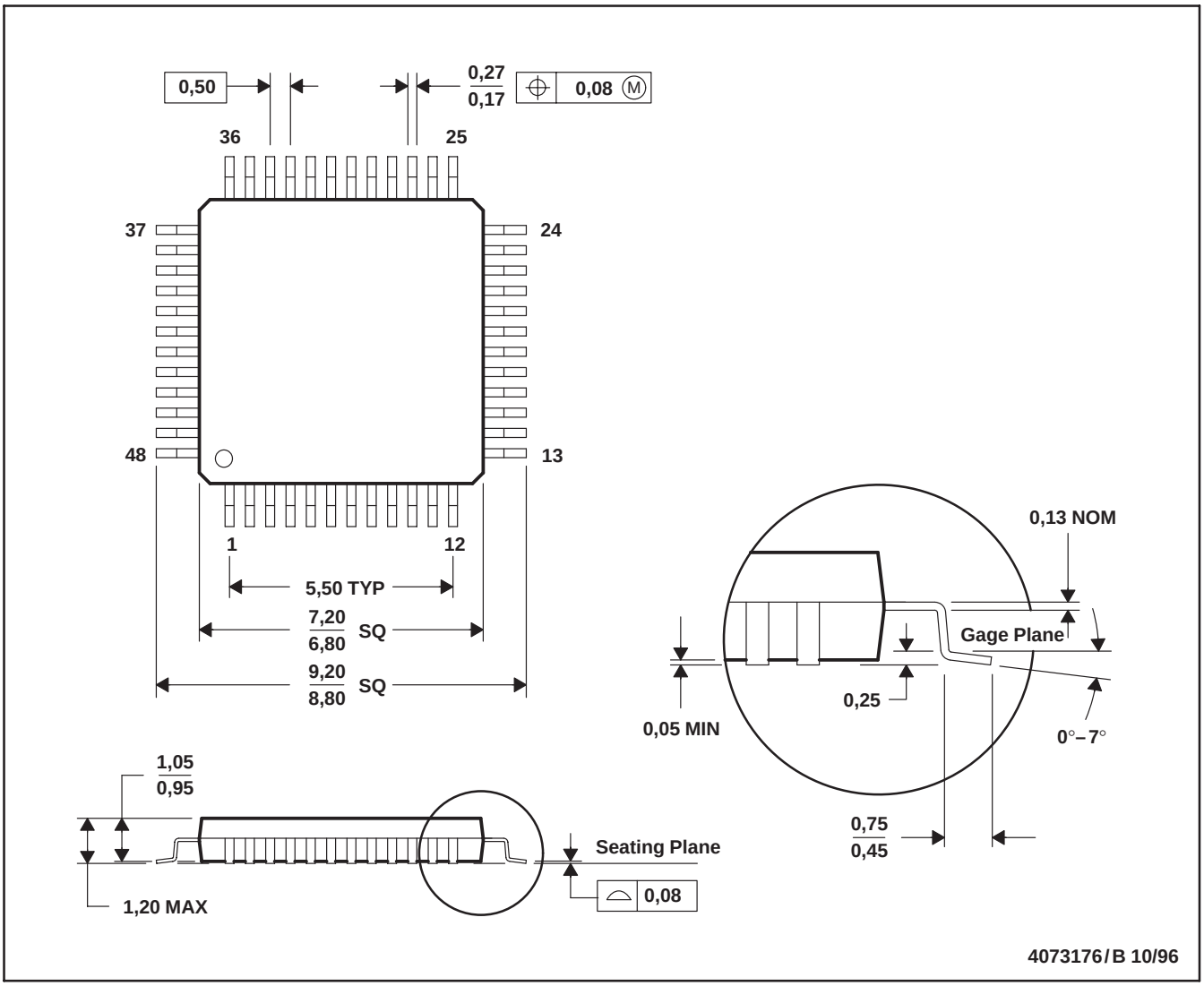

Chamfer on Tray corner indicates Pin 1 orientation of packed units.

*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | Unit array matrix | Max temperature (°C) | L (mm) | W (mm) | K0 (µm) | P1 (mm) | CL (mm) | CW (mm) |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| ADC10D020CIVS/NOPB | PFB | TQFP | 48 | 250 | 10 x 25 | 150 | 315 | 135.9 | 7620 | 12.2 | 11.1 | 11.25 |

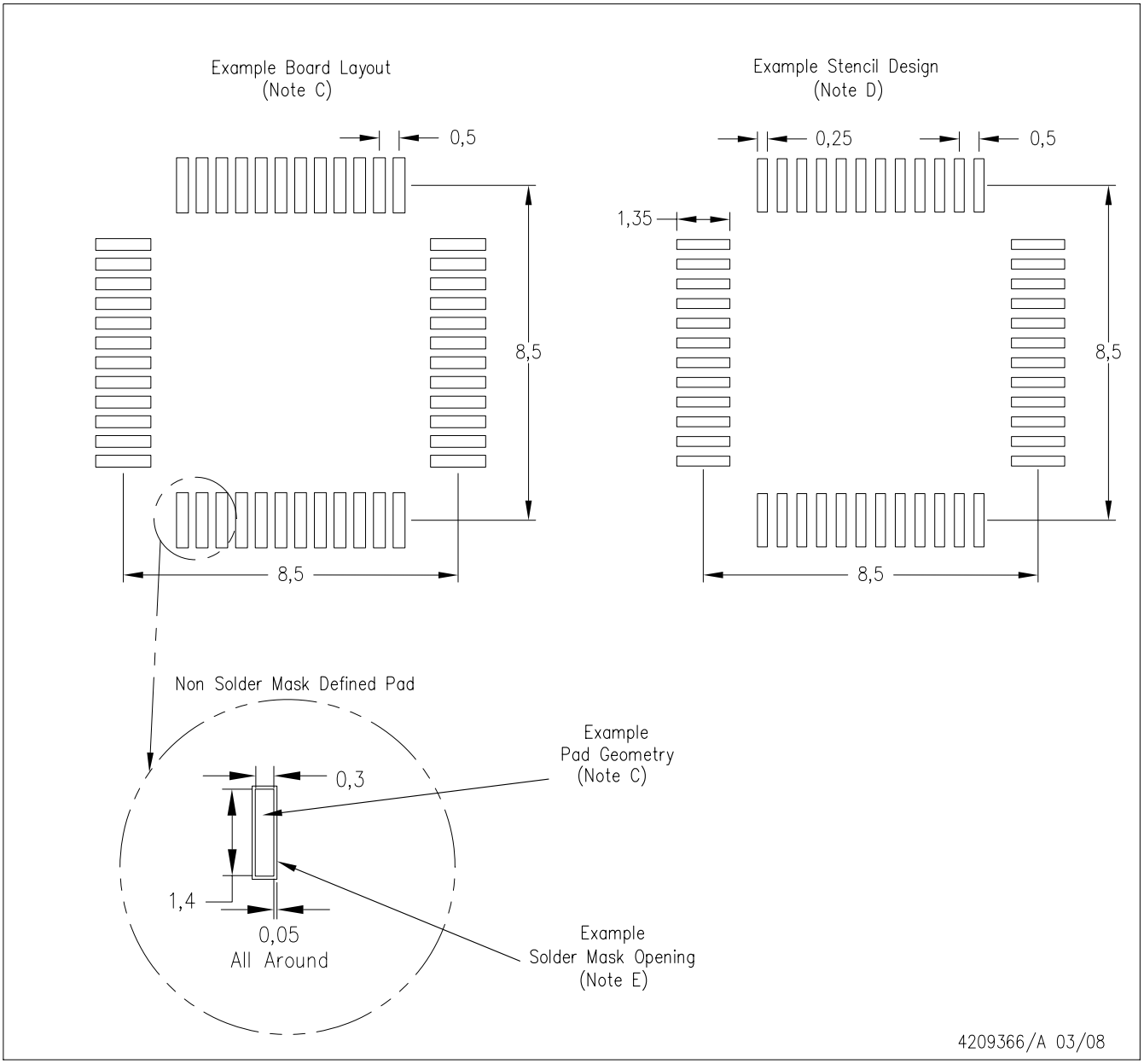
MTQF019A – JANUARY 1995 – REVISED JANUARY 1998

**PFB (S-PQFP-G48)** **PLASTIC QUAD FLATPACK**




NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-026

PFB (S–PQFP–G48)




NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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